MCP2021/2

LIN Transceiver with Voltage Regulator

Features

- The MCP2021 and MCP2022 are compliant with LIN Bus Specifications 1.3, 2.0, and 2.1 and are compliant to SAE J2602
- Support Baud Rates up to 20 Kbaud with LIN-compatible output driver
- 43V load dump protected
- Very low EMI meets stringent OEM requirements
- Wide supply voltage, 6.0V - 18.0V continuous:
  - Maximum input voltage of 30V
- Extended Temperature Range: -40 to +125°C
- Interface to PIC EUSART and standard USARTs
- Local Interconnect Network (LIN) bus pin:
  - Internal pull-up resistor and diode
  - Protected against ground shorts
  - Protected against loss of ground
  - High current drive
- Automatic thermal shutdown
- On-Board Voltage Regulator:
  - Output voltage of 5.0V with tolerances of ±3% overtemperature range
  - Available with alternate output voltage of 3.3V with tolerances of ±3% overtemperature range
  - Maximum continuous input voltage of 30V
  - Internal thermal overload protection
  - Internal short circuit current limit
  - External components limited to filter capacitor only and load capacitor
- Two low-power modes:
  - Receiver on, Transmitter off, voltage regulator on (≅ 85 µA)
  - Receiver monitoring bus, Transmitter off, voltage regulator off (≅ 16 µA)

LOCAL INTERCONNECT NETWORK

Description

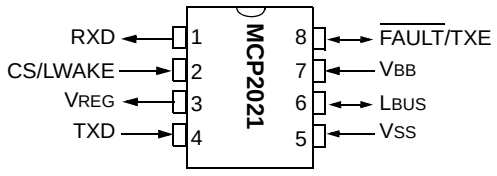
The MCP2021/2 provides a bidirectional, half-duplex communication physical interface to automotive, and industrial LIN systems to meet the LIN bus specification Revision 2.0. The device incorporates a voltage regulator with 5V @ 50 mA or 3.3V @ 50 mA regulated power supply output. The regulator is short circuit protected, and is protected by an internal thermal shut-down circuit. The regulator has been specifically designed to operate in the automotive environment and will survive reverse battery connections, +43V load dump transients, and double-battery jumps. The device has been designed to meet the stringent quiescent current requirements of the automotive industry.

MCP2021/2 family members:

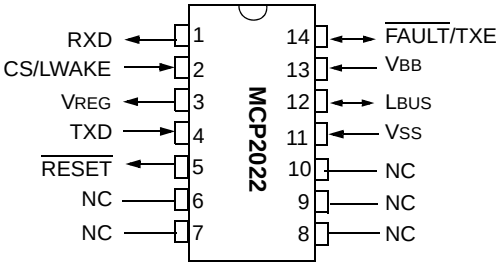
- 8-pin PDIP, DFN and SOIC packages:
  - MCP2021-330, LIN-compatible driver, 8-pin, 3.3V regulator
  - MCP2021-500, LIN-compatible driver, 8-pin, 5.0V regulator
- 14-lead PDIP, TSSOP and SOIC packages with RESET output:
  - MCP2022-330, LIN-compatible driver, 14-pin, 3.3V regulator
  - MCP2022-500, LIN-compatible driver, 14-pin, 5.0V regulator

Package Types

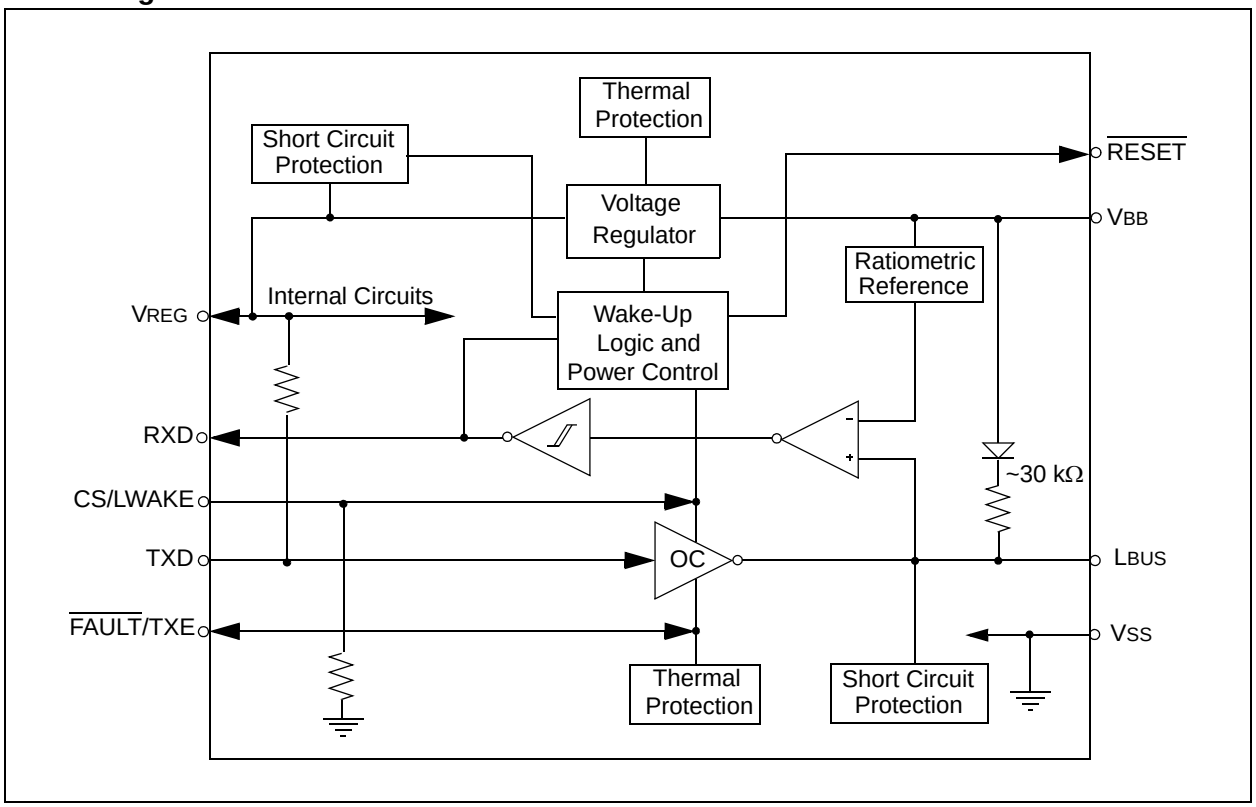
DFN-8, PDIP-8, SOIC-8



PDIP-14, SOIC-14, TSSOP-14



Block Diagram



1.0 DEVICE OVERVIEW

The MCP2021/2 provides a physical interface between a microcontroller and a LIN half-duplex bus. It is intended for automotive and industrial applications with serial bus speeds up to 20 Kbaud.

The MCP2021/2 provides a half-duplex, bidirectional communications interface between a microcontroller and the serial network bus. This device will translate the CMOS/TTL logic levels to LIN level logic, and vice versa.

The LIN specification 2.0 requires that the transceiver of all nodes in the system be connected via the LIN pin, referenced to ground and with a maximum external termination resistance of 510Ω from LIN bus to battery supply. The 510Ω corresponds to 1 Master and 16 Slave nodes.

The MCP2021-500 provides a +5V 50 mA regulated power output. The regulator uses a LDO design, is short-circuit-protected and will turn the regulator output off if it falls below 3.5V. The MCP2021/2 also includes thermal shutdown protection. The regulator has been specifically designed to operate in the automotive environment and will survive reverse battery connections, +43V load dump transients and double-battery jumps. The other members of the MCP2021-330 family output +3.3V at 50 mA with a turn-off voltage of 2.5V. (see **Section 1.6 "Internal Voltage Regulator"**).

1.1 Optional External Protection

1.1.1 REVERSE BATTERY PROTECTION

An external reverse-battery-blocking diode should be used to provide polarity protection (see Example 1-1).

1.1.2 TRANSIENT VOLTAGE PROTECTION (LOAD DUMP)

An external 43V transient suppressor (TVS) diode, between V_{BB} and ground, with a 50Ω transient protection resistor (R_{TP}) in series with the battery supply and the V_{BB} pin serve to protect the device from power transients (see Example 1-1) and ESD events. While this protection is optional, it should be considered as good engineering practice.

EQUATION 1-1:

$$R_{TP} <= (V_{BB_{min}} - 5.5) / 250\ mA.$$
$$5.5V = V_{UVLO} + 1.0V,$$
250 mA is the peak current at power-on when $V_{BB} = 5.5V$

1.2 Internal Protection

1.2.1 ESD PROTECTION

For component-level ESD ratings, please refer to the maximum operation specifications.

1.2.2 GROUND LOSS PROTECTION

The LIN Bus specification states that the LIN pin must transition to the recessive state when ground is disconnected. Therefore, a loss of ground effectively forces the LIN line to a hi-impedance level.

1.2.3 THERMAL PROTECTION

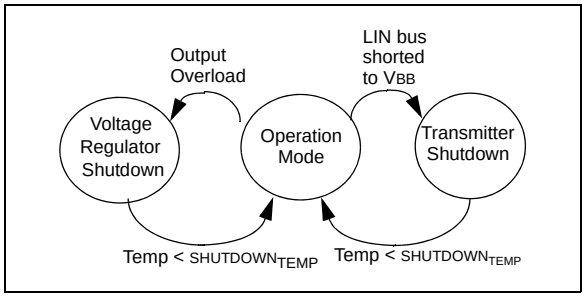
The thermal protection circuit monitors the die temperature and is able to shut down the LIN transmitter and voltage regulator.

There are three causes for a thermal overload. A thermal shut down can be triggered by any one, or a combination of, the following thermal overload conditions.

- Voltage regulator overload
- LIN bus output overload
- Increase in die temperature due to increase in environment temperature

Driving the TXD and checking the RXD pin makes it possible to determine whether there is a bus contention (Rx = low, Tx = high) or a thermal overload condition (Rx = high, Tx = low).

FIGURE 1-1: THERMAL SHUTDOWN STATE DIAGRAMS



1.3 Modes of Operation

For an overview of all operational modes, please refer to Table 1-1.

1.3.1 POWER-ON-RESET MODE

Upon application of V_{BB}, the device enters Power-On-Reset mode (POR). During this mode, the part maintains the digital section in a reset mode and waits until the voltage on pin V_{BB} rises above the “ON” threshold (Typ. 5.75V) to enter to the Ready mode. If during the operation, the voltage on pin V_{BB} falls below the “OFF” threshold (Typ. 4.25V), the part comes back to the Power-On-Reset mode.

1.3.2 POWER-DOWN MODE

In the Power-down mode, the transmitter and the voltage regulator are both off. Only the receiver section, and the CS/LWAKE pin wake-up circuits are in operation. This is the lowest power mode.

If any bus activity (e.g. a BREAK character) or CS/LWAKE going to a high level should occur during Power-down mode, the device will immediately enter the Ready mode, enable the voltage regulator, and once the output has stabilized (approximately 0.3 ms to 1.2 ms), go to the Operation mode.

Note:	The above time interval < 1.2 ms assumes 12V V_{BB} input and no thermal shutdown event.

The part will also enter the Ready mode, followed by the Operation mode, if the CS/LWAKE pin should become active true (‘1’).

The part may only enter the Power-down mode after going through an Operation mode step.

1.3.3 READY MODE

Upon entering the Ready mode, the voltage regulator and receiver threshold detect circuit are powered up. The transmitter remains in power down mode. The device is ready to receive data but not to transmit. If a microcontroller is being driven by the voltage regulator output, it will go through a Power-on Reset and initialization sequence. The LIN pin is in the recessive state.

The device will stay in the Ready mode until the output of the voltage regulator has stabilized and CS/LWAKE pin is true (‘1’). After V_{REG} is OK and CS/LWAKE pin is true, the transmitter is enabled and the part enters the Operation mode.

On Power-on of the V_{BB} supply pin, the component will stay in the Ready mode if CS/LWAKE is low. If CS/LWAKE is high, the device will immediately enter the Operation mode.

1.3.4 OPERATION MODE

In this mode, all internal modules are operational.

The MCP2021/2 will go into the Power-down mode on the falling edge of CS/LWAKE.

1.3.5 TRANSMITTER OFF MODE

Whenever the $\overline{\text{FAULT}}$/TXE signal is low and the LBUS transmitter is off.

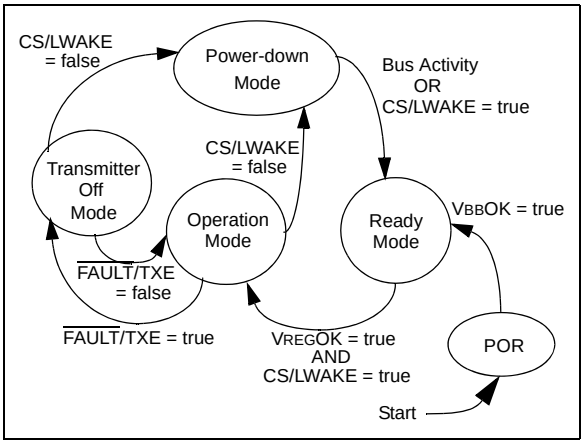
The transmitter may be re-enabled whenever the $\overline{\text{FAULT}}$/TXE signal returns high, either by removing the internal fault condition or the CPU returning the $\overline{\text{FAULT}}$/TXE high. The transmitter will not be enabled if the $\overline{\text{FAULT}}$/TXE pin is brought high when the internal fault is still present.

The transmitter is also turned off whenever the voltage regulator is unstable or recovering from a fault. This prevents unwanted disruption of the bus during times of uncertain operation.

1.3.5.1 Wake-up

The Wake-up sub module observes the LBUS in order to detect bus activity. Bus activity is detected when the voltage on the LBUS stays below a threshold of approximately 3V for at least a typical duration of 10 µs. Such a condition causes the device to leave the Power-down mode.

FIGURE 1-2: OPERATIONAL MODES STATE DIAGRAMS



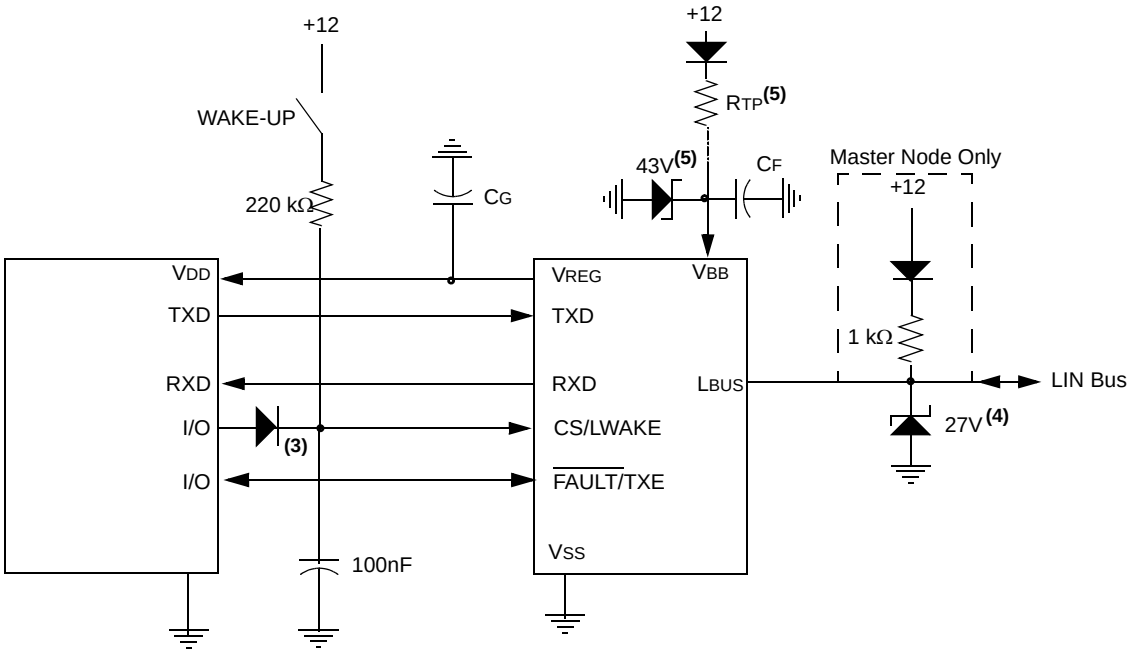
Note:	While the MCP2021/2 is in shutdown, TXD should not be actively driven high or it may power internal logic through the ESD diodes and may damage the device.

TABLE 1-1: OVERVIEW OF OPERATIONAL MODES

State	Transmitter	Receiver	Voltage Regulator	Operation	Comments
POR	OFF	OFF	OFF	Read CS/LWAKE, if LOW, then READY, if HIGH, Operational mode	
READY	OFF	Activity Detect	ON	If CS/LWAKE high level, then Operation mode	Bus Off state
OPERATION	ON	ON	ON	If CS/LWAKE low level, then Power down If FAULT/TXE low level, then Transmitter-Off mode	Normal Operation mode
POWER DOWN	OFF	Activity Detect	OFF	On LIN bus falling, go to READY mode. On CS/LWAKE high level, go to Operational mode	Low Power mode
TRANSMITTER-OFF	OFF	ON	ON	If CS/LWAKE low level, then Power down If FAULT/TXE high, then Operation mode	

1.4 Typical Applications

EXAMPLE 1-1: TYPICAL MCP2021 APPLICATION



Note 1: See Figure 2-3 for correct capacity and ESR for stable operation.

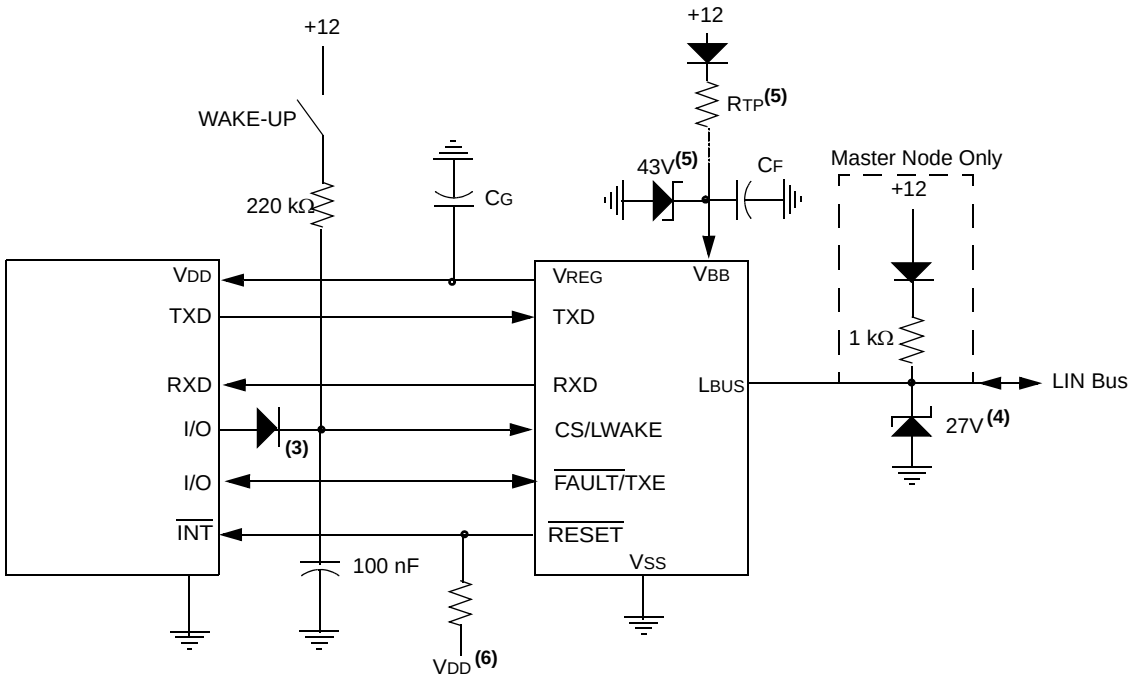
2: C_F is the filter capacitor for the external voltage supply.

3: This diode is only needed if CS/LWAKE is connected to 12V supply.

4: Transient suppressor diode. Vclamp L = 43V.

5: These components are required for additional load dump protection above 43V..

EXAMPLE 1-2: TYPICAL MCP2022 APPLICATION



Note 1: See Figure 2-3 for correct capacity and ESR for stable operation.

2: C_F is the filter capacitor for the external voltage supply.

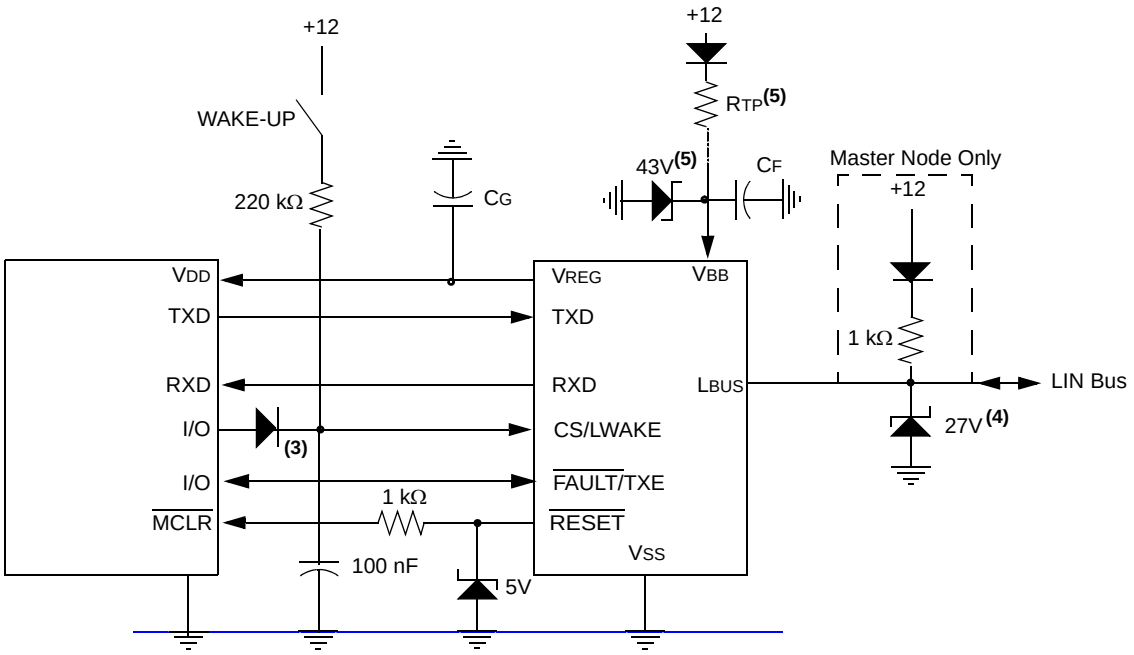
3: This diode is only needed if CS/LWAKE is connected to 12V supply.

4: Transient suppressor diode. Vclamp L = 43V.

5: These components are required for additional load dump protection above 43V.

6: Required if CPU does not have internal pullup.

EXAMPLE 1-3: TYPICAL MCP2022 APPLICATION



Note 1: See Figure 2-3 for correct capacity and ESR for stable operation.

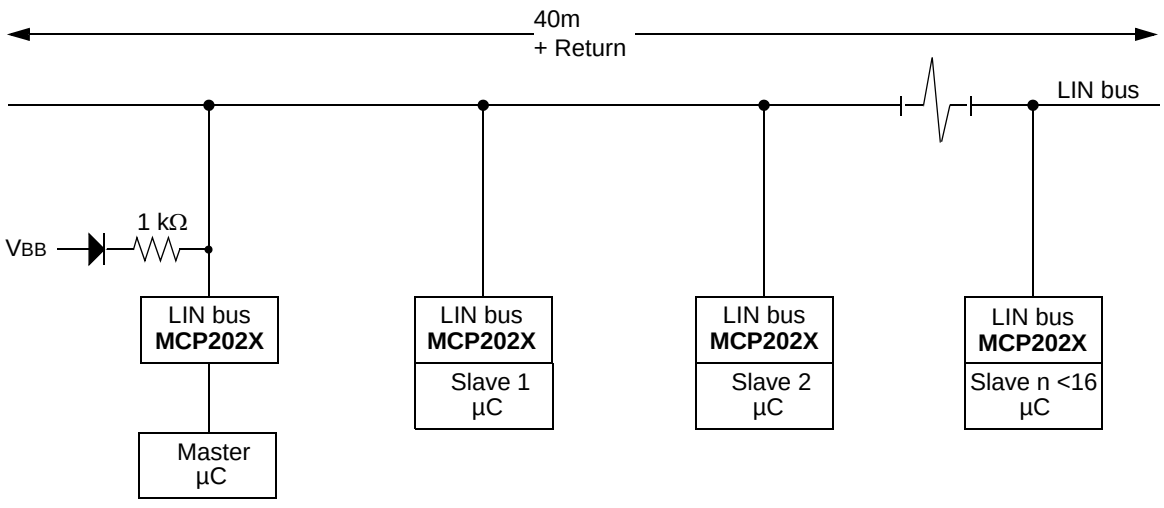
2: CF is the filter capacitor for the external voltage supply.

3: This diode is only needed if CS/LWAKE is connected to 12V supply.

4: Transient suppressor diode. Vclamp L = 43V.

5: These components are required for additional load dump protection above 43V.

FIGURE 1-3: TYPICAL LIN NETWORK CONFIGURATION



1.5 Pin Descriptions

TABLE 1-1: PINOUT DESCRIPTIONS

Pin Name	Devices		Pin Type	Function
	8-Pin DFN, PDIP, SOIC	14-Pin PDIP, SOIC, TSSOP		Normal Operation
VREG	3	3	O	Power Output
VSS	5	11	P	Ground
VBB	7	13	P	Battery Supply
TXD	4	4	I	Transmit Data Input (TTL)
RXD	1	1	O	Receive Data Output (CMOS)
LBUS	6	12	I/O	LIN bus (bidirectional)
CS/LWAKE	2	2	TTL	Chip Select (TTL)
$\overline{\text{FAULT}}$/TXE	8	14	OD	Fault Detect Output, Transmitter Enable (OD)
$\overline{\text{RESET}}$	—	5	OD	$\overline{\text{RESET}}$ signal Output (OD)

Legend: TTL = TTL input buffer, ST = Schmitt Trigger input buffer, OD = Open-Drain output, P = Power, O = Output, I = Input

1.5.1 POWER OUTPUT (VREG)

Positive Supply Voltage Regulator Output pin.

1.5.2 GROUND (VSS)

Ground pin.

1.5.3 BATTERY (VBB)

Battery Positive Supply Voltage pin. This pin is also the input for the internal voltage regulator.

1.5.4 TRANSMIT DATA INPUT (TXD)

The Transmit Data Input pin has an internal pull-up to VREG. The LIN pin is low (dominant) when TXD is low, and high (recessive) when TXD is high.

For extra bus security, TXD is internally forced to '1' when VREG is less than 1.8V (typ.).

In case the thermal protection detects an over-temperature condition while the signal TXD is low, the transmitter is shutdown. The recovery from the thermal shutdown is equal to adequate cooling time.

1.5.5 RECEIVE DATA OUTPUT (RXD)

The Receive Data Output pin is a standard CMOS output and follows the state of the LIN pin.

1.5.6 LIN BUS

The bidirectional LIN bus Interface pin is the driver unit for the LIN pin and is controlled by the signal TXD. LIN has an open collector output with a current limitation. To reduce EMI, the edges during the signal changes are slope-controlled. To further reduce radiated emissions, the LBUS pin has corner-rounding control for both falling and rising edges.

The internal LIN Receiver observes the activities on LIN bus, and generates the output signal RXD that follows the state of the LBUS. A 1st degree 1 MHz, low-pass input filter is placed to maintain EMI immunity.

1.5.7 CS/LWAKE

Chip Select Input pin. A internal pull-down resistor will keep the CS/LWAKE pin low. This is done to ensure that no disruptive data will be present on the bus while the microcontroller is executing a Power-on Reset and I/O initialization sequence. The pin must see a high level to activate the transmitter.

If CS/LWAKE= '0' when the VBB supply is turned on, the device stays in Ready mode (Low-power mode). In Ready mode, both the receiver and the voltage regulator are on and the LIN transmitter driver is off.

If CS/LWAKE = '1' when the VBB supply is turned on, the device will proceed to the Operation mode as soon as the VREG output has stabilised.

This pin may also be used as a local wake-up input (See Example 1-1). In this implementation, the microcontroller will set the I/O pin that controls the CS/LWAKE as an high-impedance input. The internal pull-down resistor will keep the input low. An external switch, or other source, can then wake-up both the transceiver and the microcontroller.

Note: CS/LWAKE should not be tied directly to VREG as this could force the MCP202x into Operation Mode before the microcontroller is initialized.

1.5.8 $\overline{\text{FAULT}}$/TXE

Fault Detect output and Transmitter Enable input bidirectional pin.

This pin is an open-drain output. Its state is defined as shown in Table 1-2. The transmitter driver is disabled whenever this pin is low (‘0’), either from an internal fault condition or by external drive. This allows the transmitter to be placed in an off state and still allow the voltage regulator to operate. Refer to Table 1-1.

The $\overline{\text{FAULT}}$/TXE also signals a mismatch between the TXD input and the LBUS level. This can be used to detect a bus contention. Since the bus exhibits a propagation delay, the sampling of the internal compare is debounced to eliminate false faults.

This pin has an internal pull-up resistor of approximately 750 kΩ.

Note 1: The $\overline{\text{FAULT}}$/TXE pin is true (0) whenever the internal circuits have detected a short or thermal excursion and have disabled the LBUS output driver.

2: $\overline{\text{FAULT}}$/TXE is true (0) when VREG not OK and has disabled the LBUS output driver.

The $\overline{\text{FAULT}}$/TXE pin sampled at a rate faster than every 10 µs.

TABLE 1-2: $\overline{\text{FAULT}}$/TXE TRUTH TABLE

TXD In	RXD Out	LINBUS I/O	Thermal Override	$\overline{\text{FAULT}}$/TXE		Definition
				External Input	Driven Output	
L	H	VBB	OFF	H	L	**FAULT**, TXD driven low, LINBUS shorted to VBB **(Note 1)**
H	H	VBB	OFF	H	H	**OK**
L	L	GND	OFF	H	H	**OK**
H	L	GND	OFF	H	H	**OK**, data is being received from the LINBUS
x	x	VBB	ON	H	L	**FAULT**, Tranceiver in thermal shutdown
x	x	VBB	x	L	x	**NO FAULT**, the CPU is commanding the tranceiver to turn off the transmitter driver

Legend: x = don’t care

Note 1: The $\overline{\text{FAULT}}$/TXE is valid after approximately 25 µs after TXD falling edge. This is to eliminate false fault reporting during bus propagation delays.

1.5.9 $\overline{\text{RESET}}$

$\overline{\text{RESET}}$ is an open-drain output pin. This pin tracks an internal signal that tracks the internal system voltage has reached a valid, stable level. As long as the internal voltage is valid, this pin will remain high (‘1’). When the system voltage drops below the minimum required, the voltage regulator will shut down and immediately convert the $\overline{\text{RESET}}$ output to (‘0’). When connected to a micro-controller input, this can provide a warning that the voltage regulator is shutting down (see Example 1-2). Alternately, it can act as an external brown-out by connecting the $\overline{\text{RESET}}$ output to MCLR (see Example 1-3). In addition to monitoring the internal voltage, $\overline{\text{RESET}}$ is asserted immediately upon entering the Powerdown mode.

1.6 Internal Voltage Regulator

1.6.1 5.0V REGULATOR

The MCP2021 has a low-drop-out voltage, positive regulator capable of supplying 5.00 VDC ±3% at up to 50 mA of load current over the entire operating temperature range of -40°C to +125°C. With a load current of 50 mA, the minimum input to output voltage differential required for the output to remain in regulation is typically +0.5V (+1V maximum over the full operating temperature range). Quiescent current is less than 100 µA with a full 50 mA load current when the input to output voltage differential is greater than +3.00V.

The regulator requires an external output bypass capacitor for stability. See Figure 2-3 for correct capacity and ESR for stable operation.

Designed for automotive applications, the regulator will protect itself from double-battery jumps and up to +43V load dump transients. The voltage regulator has both short-circuit and thermal shutdown protection built-in.

Regarding the correlation between VBB, VREG and IDD, please refer to Figure 1-5 through 1-7. When the input voltage (VBB) drops below the differential needed to provide stable regulation, the output Vreg will track the input down to approximately 3.5V, at which point the regulator will turn off. This will allow microcontrollers with internal POR circuits to generate a clean arming of the Power-on Reset trip point. The MCP2021 will then monitor VBB and turn on the regulator when Vbb is 6.0V.

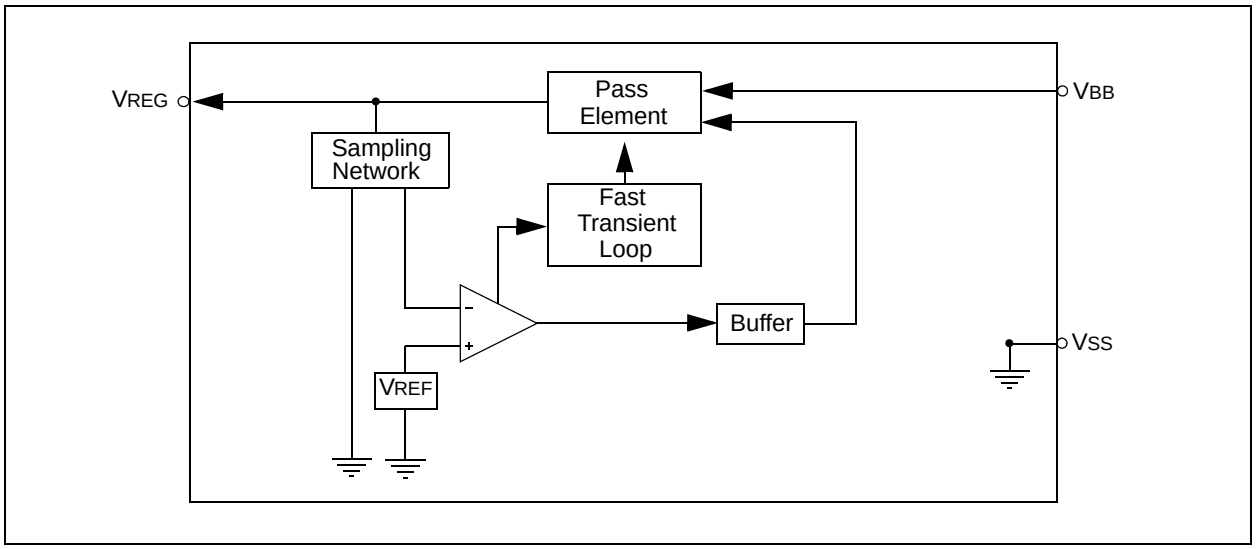
When the input voltage (VBB) drops below the differential needed to provide stable regulation, the output VREG) will track the input down to approximately +4.25V. The regulator will turn off the output at this point. This will allow PIC® microcontrollers, with internal POR circuits, to generate a clean arming of the Power-on Reset trip point. The regulator output will stay off until VBB is above +5.75 V_{DC}.

In the start phase, the device must see at least 6.0V to initiate operation during power up. In the Power-down mode, the VBB monitor will be turned off.

Note:	The regulator has an overload current limiting of approximately 100 mA. During a short circuit, the VREG is monitored. If VREG is lower than 3.5V, the VREG will turn off. After a recovery time of about three milliseconds, the VREG will be checked again. If there is no short circuit, (VREG > 3.5V) then the VREG will be switched back on.

The regulator has a thermal shutdown. If the thermal protection circuit detects an over temperature condition, and the signals TXD and RXD are LOW, or TXD is HIGH, the regulator will shut down. The recovery from the thermal shutdown is equal to adequate cooling time.

FIGURE 1-4: VOLTAGE REGULATOR BLOCK DIAGRAM



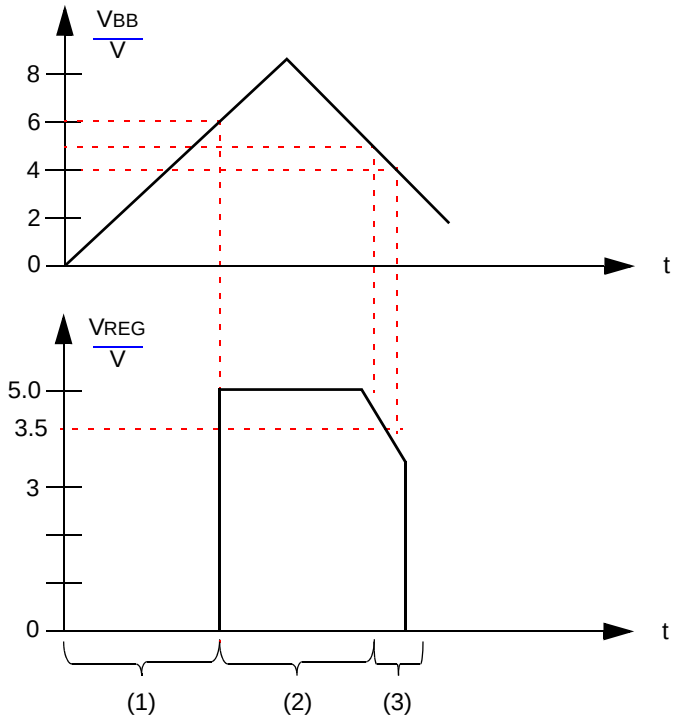
1.6.2 3.3V REGULATOR

A metal option provides for a alternate 3.30 V_{DC} ±3% at up to 50 mA of load current over the entire operating temperature range of -40°C to +125°C. All specifications given above for the 5.0V operation apply except for any difference noted here.

The same input tracking of 4.25V applies the 3.3V regulator.

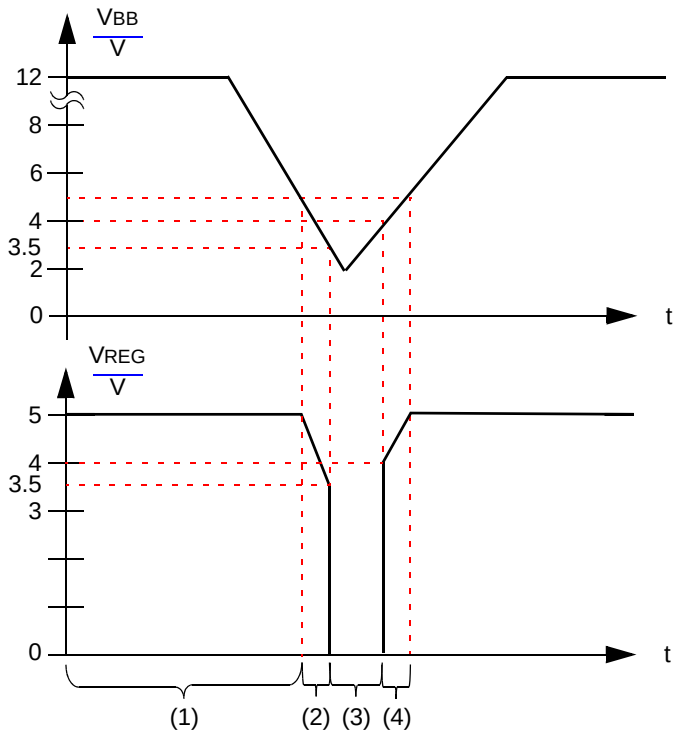
Note: The regulator has an overload current limiting of approximately 100 mA. If V_{REG} is lower than 2.5V, the V_{REG} will turn off.

FIGURE 1-5: VOLTAGE REGULATOR OUTPUT ON POWER-ON RESET



Note 1: Start-up, V_{BB} < 5.75V, regulator off.
2: V_{BB} > 5.75V, regulator on.
3: $V_{BB} \leq$ 5.5V, regulator tracks V_{BB}
4: V_{BB} < 4.25V, regulator will turn off

FIGURE 1-6: VOLTAGE REGULATOR OUTPUT ON POWER DIP



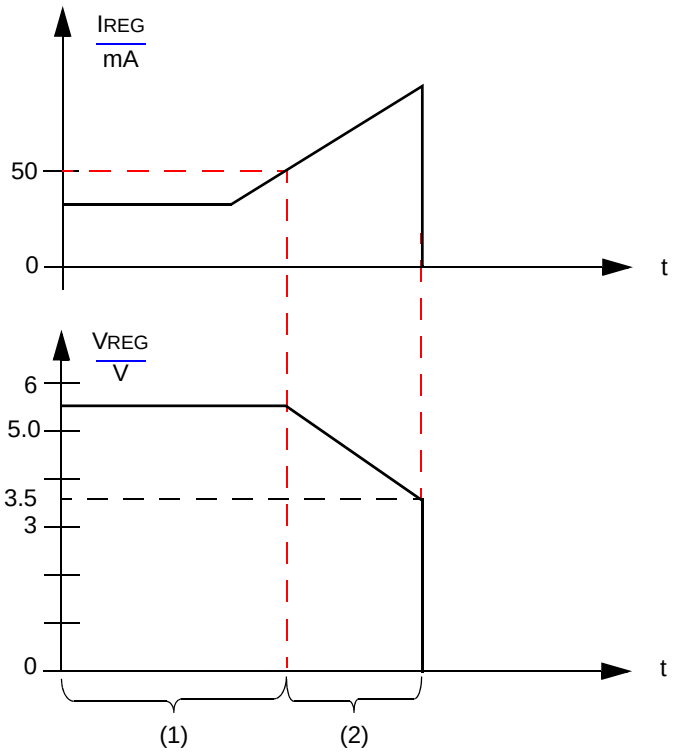
Note 1: Voltage regulator on.

2: $V_{BB} \leq 5.5V$, regulator tracks V_{BB} until $V_{BB} < 4.25V$.

3: $V_{REG} < 3.5V$, regulator is off.

4: $V_{BB} > 5.75V$, regulator on.

FIGURE 1-7: VOLTAGE REGULATOR OUTPUT ON OVERCURRENT SITUATION



Note 1: IREG less than 50 mA, regulator on.

2: After IREG exceeds IREGmax, voltage regulator output will be reduced until VREG off is reached.

1.7 ICSP™ Considerations

The following should be considered when the MCP2021/2 is connected to pins supporting in-circuit programming:

- Power used for programming the microcontroller can be supplied from the programmer, or from the MCP2021/2.
- The voltage on VREG should not exceed the maximum output voltage of VREG.

NOTES:

2.0 ELECTRICAL CHARACTERISTICS

2.1 Absolute Maximum Ratings†

V_{IN} DC Voltage on RXD and TXD ..... -0.3 to V_{REG}+0.3V
V_{IN} DC Voltage on $\overline{FAULT}$ and $\overline{RESET}$ ..... -0.3 to +5.5V
V_{IN} DC Voltage on CS/LWAKE ..... -0.3 to +43V
V_{BB} Battery Voltage, non-operating (LIN bus recessive, no regulator load, t < 60s) ..... -0.3 to +43V
V_{BB} Battery Voltage, transient ISO 7637 Test 1 ..... -200V
V_{BB} Battery Voltage, transient ISO 7637 Test 2a ..... +150V
V_{BB} Battery Voltage, transient ISO 7637 Test 3a ..... -300V
V_{BB} Battery Voltage, transient ISO 7637 Test 3b ..... +200V
V_{BB} Battery Voltage, continuous ..... -0.3 to +30V
V_{LBUS} Bus Voltage, continuous ..... -18 to +30V
V_{LBUS} Bus Voltage, transient (**Note 1**) ..... -27 to +43V
I_{LBUS} Bus Short Circuit Current Limit ..... 200 mA
ESD protection on LIN, V_{BB} (IEC 61000-4-2, 330 Ohm, 150 pF) (**Note 3**) ..... minimum ±9 kV
ESD protection on LIN, V_{BB} (Charge Device Model) (**Note 2**) ..... ±1500V
ESD protection on LIN, VBB (Human Body Model, 1 kOhm, 100 pF) (**Note 4**) ..... ±8 kV
ESD protection on LIN, V_{BB} (Machine Model) (**Note 2**) ..... ±800V
ESD protection on all other pins (Human Body Model) (**Note 2**) ..... > 4 kV
Maximum Junction Temperature ..... 150°C
Storage Temperature ..... -55 to +150°C

Note 1: ISO 7637/1 load dump compliant (t < 500 ms).

2: According to JESD22-A114-B.

3: According to IBEE, without bus filter.

4: Limited by Test Equipment.

† **NOTICE**: Stresses above those listed under “Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

2.2 DC Specifications

DC Specifications	**Electrical Characteristics:** Unless otherwise indicated, all limits are specified for: V_{BB} = 6.0V to 18.0V T_A = -40°C to +125°C $C_{LOADREG}$ = 10 µF					
Parameter	**Sym**	**Min.**	**Typ.**	**Max.**	**Units**	**Conditions**
Power						
V_{BB} Quiescent Operating Current	I_{BBQ}		115	210	µA	I_{OUT} = 0 mA, L_{BUS} recessive
		—	120	215	µA	V_{OUT} = 3.3V
V_{BB} Transmitter-off Current	I_{BBTO}	—	90	190	µA	With V_{REG} on, transmitter off, receiver on, $\overline{FAULT}$/TXE = V_{IL}, CS = V_{IH}
		—	95	210	µA	V_{OUT} = 3.3V
V_{BB} Power-down Current	I_{BBPD}	—	16	26	µA	With V_{REG} powered-off, receiver on and transmitter off, $\overline{FAULT}$/TXE = V_{IH}, TXD = V_{IH}, CS = V_{IL})
V_{BB} Current with V_{SS} Floating	$I_{BBNOGND}$	-1	—	1	mA	V_{BB} = 12V, GND to V_{BB}, VLIN = 0-18V
Microcontroller Interface						
High Level Input Voltage (TXD, $\overline{FAULT}$/TXE)	V_{IH}	2.0 or (0.25V_{REG} +0.8)	—	V_{REG} +0.3	V	
Low Level Input Voltage (TXD, $\overline{FAULT}$/TXE)	V_{IL}	-0.3	—	0.15 V_{REG}	V	
High Level Input Current (TXD, $\overline{FAULT}$/TXE)	I_{IH}	-2.5	—	—	µA	Input voltage = 0.8*V_{REG}
Low Level Input Current (TXD, $\overline{FAULT}$/TXE)	I_{IL}	-10	—	—	µA	Input voltage = 0.2*V_{REG}
Pull-up Current on Input (TXD)	I_{PU}TXD	-3.0	—	—	µA	~800 kΩ internal pull-up to V_{REG} @ V_{IH} = 0.7*V_{REG}
High Level Input Voltage (CS/LWAKE)	V_{IH}	0.7V_{REG}	—	V_{BB}	V	Through a current-limiting resistor
Low Level Input Voltage (CS/LWAKE)	V_{IL}	-0.3	—	0.3V_{REG}	V	
High Level Input Current (CS/LWAKE)	I_{IH}	—	—	7.0	µA	Input voltage = 0.8*V_{REG}
Low Level Input Current (CS/LWAKE)	I_{IL}	—	—	3.0	µA	Input voltage = 0.2*V_{REG}
Pull-down Current on Input (CS/LWAKE)	I_{PDCS}	—	—	6.0	µA	~1.3MΩ internal pull-down to V_{SS} @ V_{IH} = 3.5V

Note 1: Internal current limited. 2.0 ms maximum recovery time (R_{LBUS} = 0Ω, TX = 0.4 V_{REG}, V_{LBUS} = V_{BB}).

2: For design guidance only, not tested.

3: Node has to sustain the current that can flow under this condition; bus must be operational under this condition.

2.2 DC Specifications (Continued)

DC Specifications	**Electrical Characteristics:** Unless otherwise indicated, all limits are specified for: V_{BB} = 6.0V to 18.0V T_A = -40°C to +125°C $C_{LOADREG}$ = 10 µF					
Parameter	**Sym**	**Min.**	**Typ.**	**Max.**	**Units**	**Conditions**
Bus Interface						
High Level Input Voltage	$V_{IH(LBUS)}$	0.6 V_{BB}	—	18	V	Recessive state
Low Level Input Voltage	$V_{IL(LBUS)}$	-8	—	0.4 V_{BB}	V	Dominant state
Input Hysteresis	V_{HYS}	—	—	0.175 V_{BB}	V	$V_{IH(LBUS)}$ - $V_{IL(LBUS)}$
Low Level Output Current	$I_{OL(LBUS)}$	40	—	200	mA	Output voltage = 0.1 V_{BB}, V_{BB} = 12V
Pull-up Current on Input	$I_{PU(LBUS)}$	5	—	180	µA	~30 kΩ internal pull-up @ V_{IH} (L_{BUS}) = 0.7 V_{BB}
Short Circuit Current Limit	I_{SC}	50	—	200	mA	**(Note 1)**
High Level Output Voltage	$V_{OH(LBUS)}$	0.8 V_{BB}	—	V_{BB}	V	$V_{OH(LBUS)}$ must be at least 0.8 V_{BB}
Low Level Output Voltage	V_{OLLO} (L_{BUS})	—	—	0.2 V_{BB}	V	
Input Leakage Current (at the receiver during dominant bus level)	$I_{BUS\_PAS\_DOM}$	-1	—	—	mA	Driver off, V_{BUS} = 0V, V_{BAT} = 12V
Leakage Current (disconnected from ground)	$I_{BUS\_NO\_GND}$	-1	—	+1	mA	GND_{DEVICE} = V_{BAT}, 0V < V_{BUS} < 18V, V_{BAT} = 12V
Leakage Current (disconnected from V_{BAT})	I_{BUS}	—	—	10	µA	V_{BAT} = GND, 0 < V_{BUS} < 18V, T_A = -40°C to +85°C **(Note 3)**
				50	µA	T_A = +85°C to +125°C
Receiver Center Voltage	V_{BUS_CNT}	0.475 V_{BB}	0.5 V_{BB}	0.525 V_{BB}	V	V_{BUS_CNT} = (V_{IL} (L_{BUS}) + V_{IH} (L_{BUS}))/2
Slave Termination	Rslave	20	30	47	kΩ	

Note 1: Internal current limited. 2.0 ms maximum recovery time (R_{LBUS} = 0Ω, TX = 0.4 V_{REG}, V_{LBUS} = V_{BB}).

2: For design guidance only, not tested.

3: Node has to sustain the current that can flow under this condition; bus must be operational under this condition.

2.2 DC Specification (Continued)

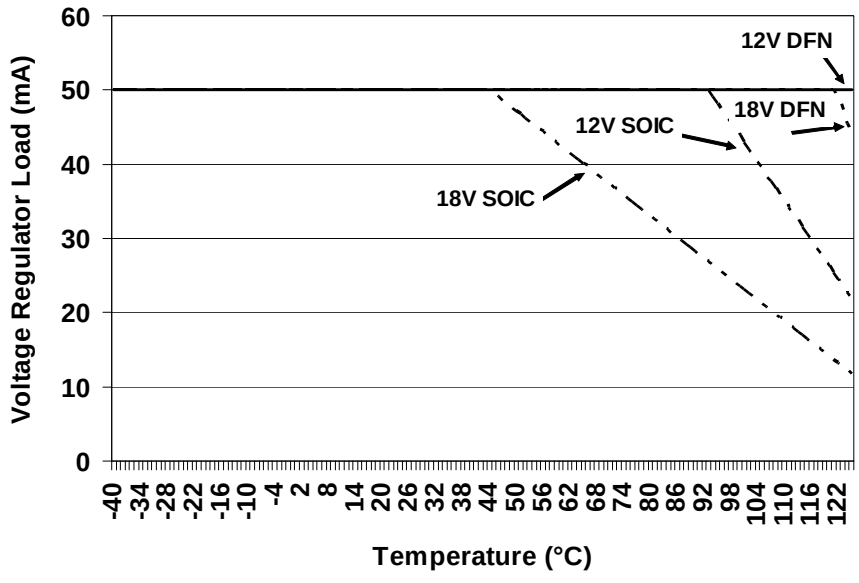
DC Specifications	**Electrical Characteristics:** Unless otherwise indicated, all limits are specified for: V_{BB} = 6.0V to 18.0V T_A = -40°C to +125°C $C_{LOADREG}$ = 10 µF					
Parameter	**Sym**	**Min.**	**Typ.**	**Max.**	**Units**	**Conditions**
Voltage Regulator - 5.0V						
Output Voltage	V_{OUT}	4.85	5.00	5.15	V	0 mA < I_{OUT} < 50 mA,
Load Regulation	$\Delta V_{OUT}2$	—	10	50	mV	5 mA < I_{OUT} < 50 mA refer to **Section 1.6 "Internal Voltage Regulator"**
Quiescent Current	I_{VRQ}	—	—	25	µA	I_{OUT} = 0 mA, **(Note 2)**
Power Supply Ripple Reject	PSRR	—	—	50	dB	1 V_{PP} @10-20 kHz C_{LOAD} = 10 µf, I_{LOAD} = 50 mA
Output Noise Voltage	eN	—	—	100	µV_{RMS}	10 Hz – 40 MHz C_{FILTER} = 10 µf, C_{BP} = 0.1 µf, C_{LOAD} 10 µf, I_{LOAD} = 50 mA
Shutdown Voltage	V_{SD}	3.5	—	4.0	V	See Figure 1-5
Input Voltage to Maintain Regulation	V_{BB}	6.0	—	18.0	V	
Input Voltage to Turn Off Output	V_{OFF}	4.0	—	4.5	V	
Input Voltage to Turn On Output	V_{ON}	5.5	—	6.0	V	

Note 1: Internal current limited. 2.0 ms maximum recovery time (R_{LBUS} = 0Ω, TX = 0.4 V_{REG}, V_{LBUS} = V_{BB}).

2: For design guidance only, not tested.

3: Node has to sustain the current that can flow under this condition; bus must be operational under this condition.

FIGURE 2-1: MCP2021-500 SAFE OPERATING RANGE



2.2 DC Specification (Continued)

DC Specifications	**Electrical Characteristics:** Unless otherwise indicated, all limits are specified for: V_{BB} = 6.0V to 18.0V T_A = -40°C to +125°C $C_{LOADREG}$ = 10 µF					
Parameter	**Sym**	**Min.**	**Typ.**	**Max.**	**Units**	**Conditions**
Voltage Regulator - 3.3V						
Output Voltage	V_{OUT}	3.20	3.30	3.40	V	0 mA < I_{OUT} < 50 mA
Line Regulation	$\Delta V_{OUT}1$	—	10	50	mV	I_{OUT} = 1 mA, 6.0V < V_{BB} < 18V
Load Regulation	$\Delta V_{OUT}2$	—	10	50	mV	5 mA < I_{OUT} < 50 mA Refer to **Section 1.6 "Internal Voltage Regulator"**
Quiescent Current	I_{VRQ}	—	—	25	µA	I_{OUT} = 0 mA, **(Note 2)**
Power Supply Ripple Reject	PSRR	—	—	50	dB	1 V_{PP} @10-20 kHz C_{LOAD} = 10 µf, I_{LOAD} = 50 mA
Output Noise Voltage	eN	—	—	100	$\mu V_{RMS}/\sqrt{Hz}$	10 Hz – 40 MHz C_{FILTER} = 10 µf, C_{BP} = 0.1 µf C_{LOAD} = 10 µf, I_{LOAD} = 50 mA
Shutdown Voltage	V_{SD}	2.5	—	2.7	V	See Figure 1-5
Input Voltage to Maintain Regulation	V_{BB}	6.0	—	18.0	V	
Input Voltage to Turn Off Output	V_{OFF}	4.0	—	4.5	V	
Input Voltage to Turn On Output	V_{ON}	5.5	—	6.0	V	

Note 1: Internal current limited. 2.0 ms maximum recovery time (R_{LBUS} = 0Ω, TX = 0.4 V_{REG}, V_{LBUS} = V_{BB}).

2: For design guidance only, not tested.

3: Node has to sustain the current that can flow under this condition; bus must be operational under this condition.

FIGURE 2-2: MCP2021-330 SAFE OPERATING RANGE

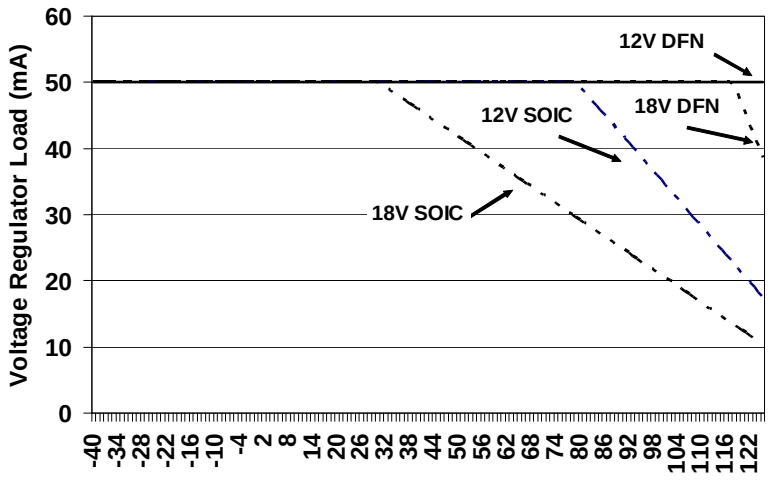
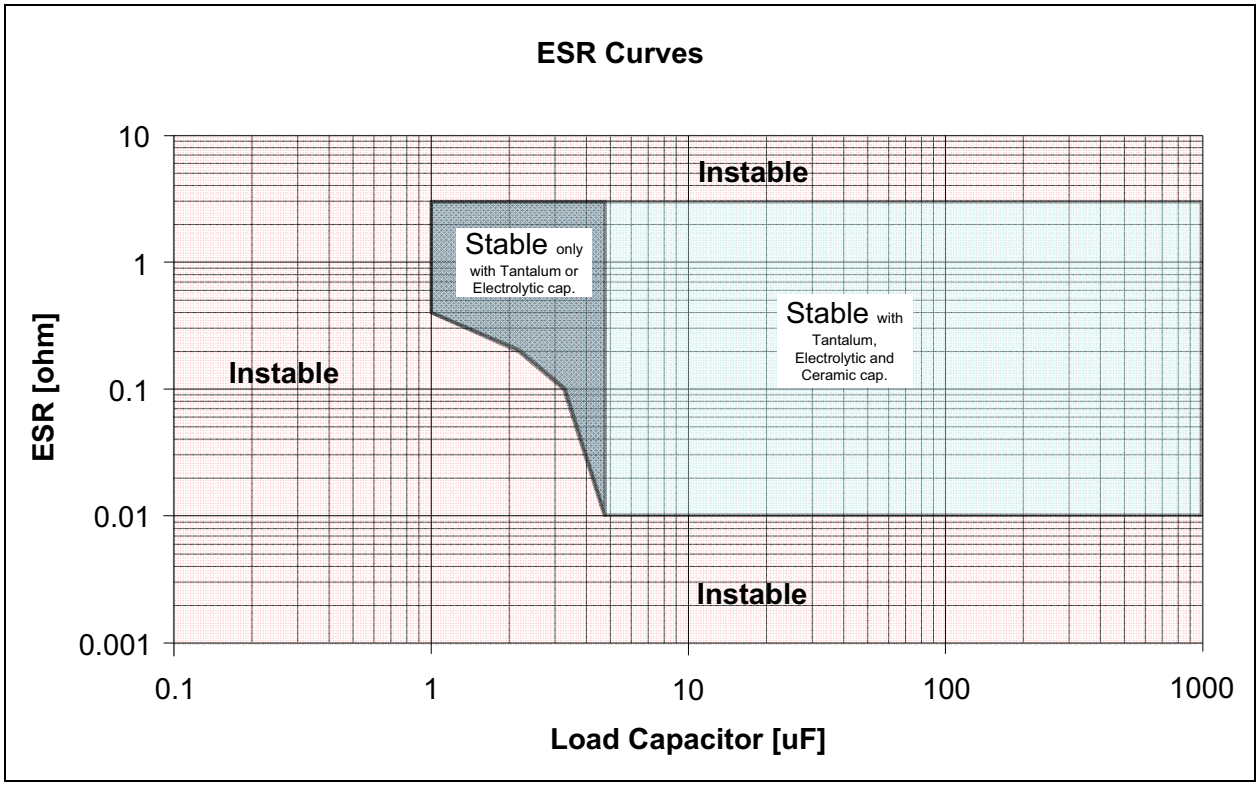


FIGURE 2-3: ESR CURVES FOR LOAD CAPACITOR SELECTION



2.3 AC Specification

AC CHARACTERISTICS	V_{BB} = 6.0V to 18.0V; T_A = -40°C to +125°C					
Parameter	**Sym**	**Min.**	**Typ.**	**Max.**	**Units**	**Test Conditions**
Bus Interface - Constant Slope Time Parameters						
Slope rising and falling edges	t_{SLOPE}	3.5	—	22.5	µs	7.3V <= V_{BB} <= 18V
Propagation Delay of Transmitter	$t_{TRANSPD}$	—	—	4.0	µs	$t_{TRANSPD}$ = max ($t_{TRANSPDR}$ or $t_{TRANSPDF}$)
Propagation Delay of Receiver	t_{RECPD}	—	—	6.0	µs	t_{RECPD} = max (t_{RECPDR} or t_{RECPDF})
Symmetry of Propagation Delay of Receiver rising edge w.r.t. falling edge	t_{RECSYM}	-2.0	—	2.0	µs	t_{RECSYM} = max (t_{RECPDF} - t_{RECPDR})
Symmetry of Propagation Delay of Transmitter rising edge w.r.t. falling edge	$t_{TRANSSYM}$	-2.0	—	2.0	µs	$t_{TRANSSYM}$ = max ($t_{TRANSPDF}$ - $t_{TRANSPDR}$)
Time to sample of FAULT/ TXE for bus conflict reporting	t_{FAULT}	—	—	32.5	µs	t_{FAULT} = max ($t_{TRANSPD}$ + t_{SLOPE} + t_{RECPD})
Duty Cycle 1 @20.0 kbit/sec		39.6	—	—	%t_{BIT}	C_{BUS};R_{BUS} conditions: 1 nF; 1 kΩ | 6.8 nF; 660Ω | 10 nF; 500Ω $TH_{REC(MAX)}$ = 0.744 x V_{BB}, $TH_{DOM(MAX)}$ = 0.581 x V_{BB}, V_{BB} =7.0V - 18V; t_{BIT} = 50 µs. D1 = $t_{BUS\_REC(MIN)}$ / 2 x t_{BIT})
Duty Cycle 2 @20.0 kbit/sec		—	—	58.1	%t_{BIT}	C_{BUS};R_{BUS} conditions: 1 nF; 1 kΩ | 6.8 nF; 660Ω | 10 nF; 500Ω $TH_{REC(MAX)}$ = 0.284 x V_{BB}, $TH_{DOM(MAX)}$ = 0.422 x V_{BB}, V_{BB} =7.6V - 18V; t_{BIT} = 50 µs. D2 = $t_{BUS\_REC(MAX)}$ / 2 x t_{BIT})
Duty Cycle 3 @10.4 kbit/sec		41.7	—	—	%t_{BIT}	C_{BUS};R_{BUS} conditions: 1 nF; 1 kΩ | 6.8 nF; 660Ω | 10 nF; 500Ω $TH_{REC(MAX)}$ = 0.778 x V_{BB}, $TH_{DOM(MAX)}$ = 0.616 x V_{BB}, V_{BB} =7.0V - 18V; t_{BIT} = 96 µs. D3 = $t_{BUS\_REC(MIN)}$ / 2 x t_{BIT})
Duty Cycle 4 @10.4 kbit/sec		—	—	59.0	%t_{BIT}	C_{BUS};R_{BUS} conditions: 1 nF; 1 kΩ | 6.8 nF; 660Ω | 10 nF; 500Ω $TH_{REC(MAX)}$ = 0.251 x V_{BB}, $TH_{DOM(MAX)}$ = 0.389 x V_{BB}, V_{BB} =7.6V - 18V; t_{BIT} = 96 µs. D4 = $t_{BUS\_REC(MAX)}$ / 2 x t_{BIT})

2.3 AC Specification (Continued)

AC CHARACTERISTICS	V_{BB} = 6.0V to 18.0V; T_A = -40°C to +125°C					
Parameter	**Sym**	**Min.**	**Typ.**	**Max.**	**Units**	**Test Conditions**
Voltage Regulator						
Bus Activity Debounce time	t_{BDB}	5	10	20	µs	Bus debounce time
Bus Activity to Voltage Regulator Enabled	t_{BACTVE}	100	250	500	µs	After Bus debounce time
Voltage Regulator Enabled to Ready	t_{VEVR}	—	—	1200	µs	**(Note 1)**
Chip Select to Operation Ready	t_{CSOR}	—	—	500	µs	**(Note 1)**
Chip Select to Power-down	t_{CSPD}	—	—	80	µs	
Short circuit to shut-down	$t_{SHUTDOWN}$	20	—	100	µs	
$\overline{\text{RESET}}$ Timing						
V_{REG} OK detect to $\overline{\text{RESET}}$ inactive	t_{RPU}	—	—	10.0	µs	
V_{REG} OK detect to $\overline{\text{RESET}}$ active	t_{RPD}	—	—	10.0	µs	

Note 1: Time depends on external capacitance and load.

2.4 Thermal Specifications

THERMAL CHARACTERISTICS					
Parameter	**Symbol**	**Typ**	**Max**	**Units**	**Test Conditions**
Recovery Temperature	$\theta_{RECOVERY}$	+140	—	°C	
Shutdown Temperature	$\theta_{SHUTDOWN}$	+150	—	°C	
Short Circuit Recovery Time	t_{THERM}	1.5	5.0	ms	
Thermal Package Resistances					
Thermal Resistance, 8L-DFN	θ_{JA}	35.7	—	°C/W	
Thermal Resistance, 8L-PDIP	θ_{JA}	89.3	—	°C/W	
Thermal Resistance, 8L-SOIC	θ_{JA}	149.5	—	°C/W	
Thermal Resistance, 14L-PDIP	θ_{JA}	70	—	°C/W	
Thermal Resistance, 14L-SOIC	θ_{JA}	95.3	—	°C/W	
Thermal Resistance, 14L-TSSOP	θ_{JA}	100	—	°C/W	

Note 1: The maximum power dissipation is a function of T_{JMAX}, Θ_{JA} and ambient temperature T_A. The maximum allowable power dissipation at an ambient temperature is $P_D = (T_{JMAX} - T_A)\ \Theta_{JA}$. If this dissipation is exceeded, the die temperature will rise above 150°C and the MCP2021 will go into thermal shutdown.

2.5 Timing Diagrams and Specifications

FIGURE 2-4: BUS TIMING DIAGRAM

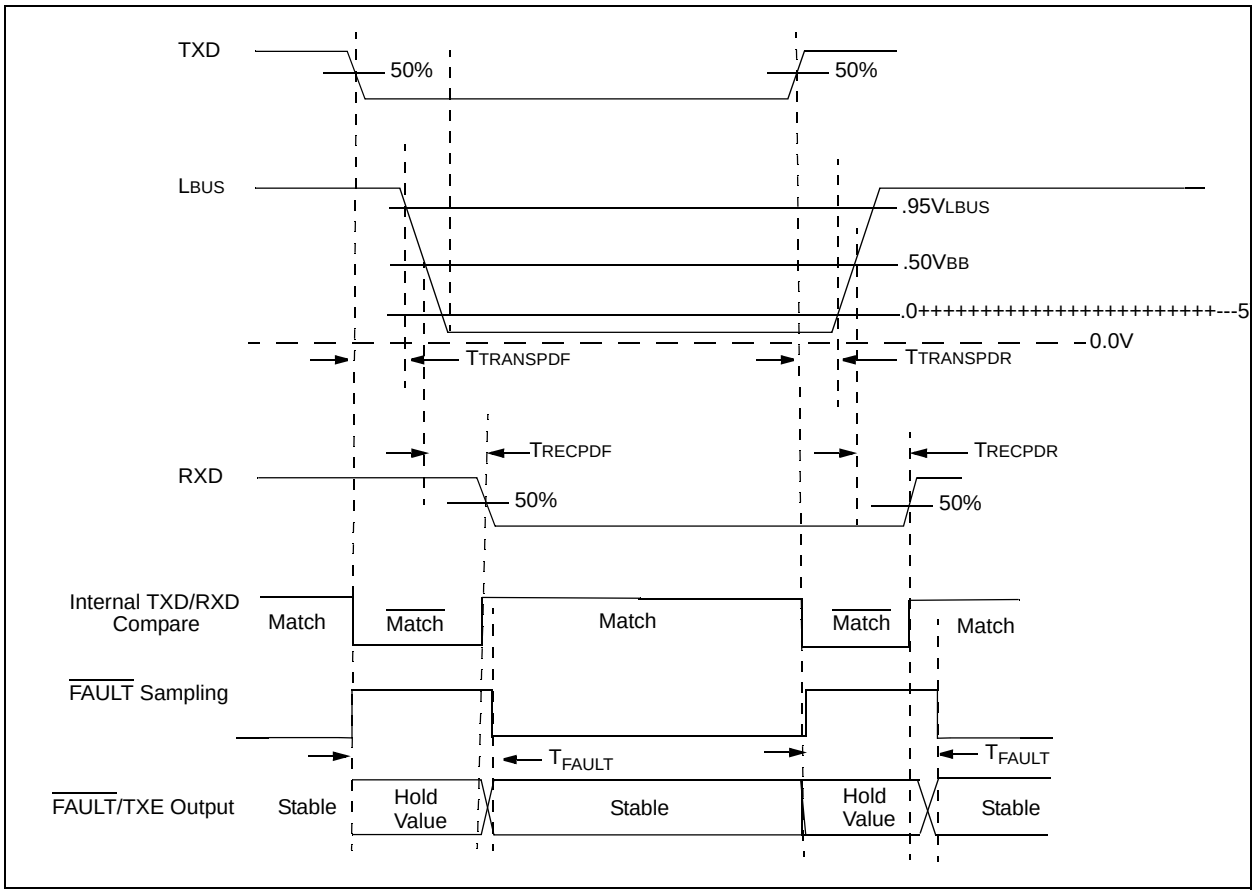


FIGURE 2-5: REGULATOR CS/LWAKE TIMING DIAGRAM

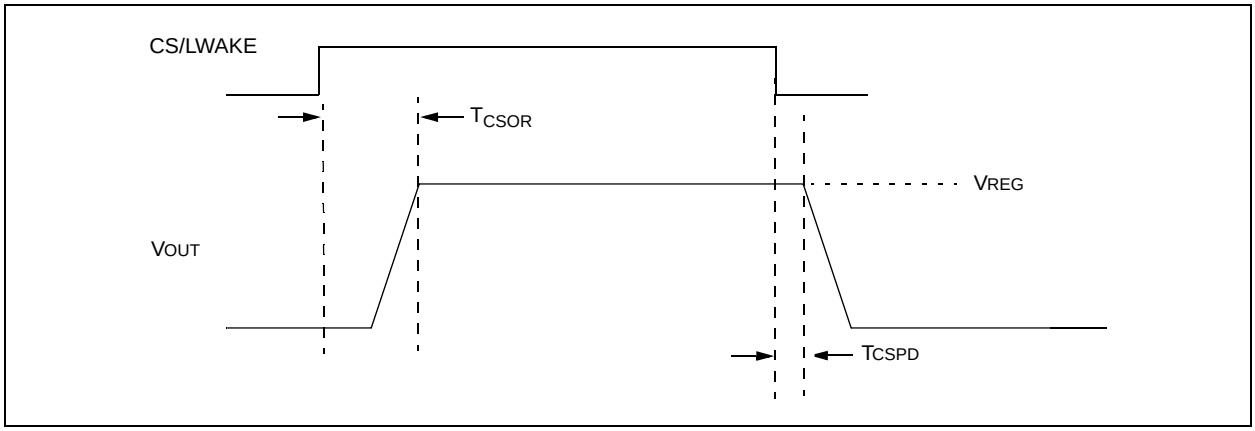


FIGURE 2-6: REGULATOR BUS WAKE TIMING DIAGRAM

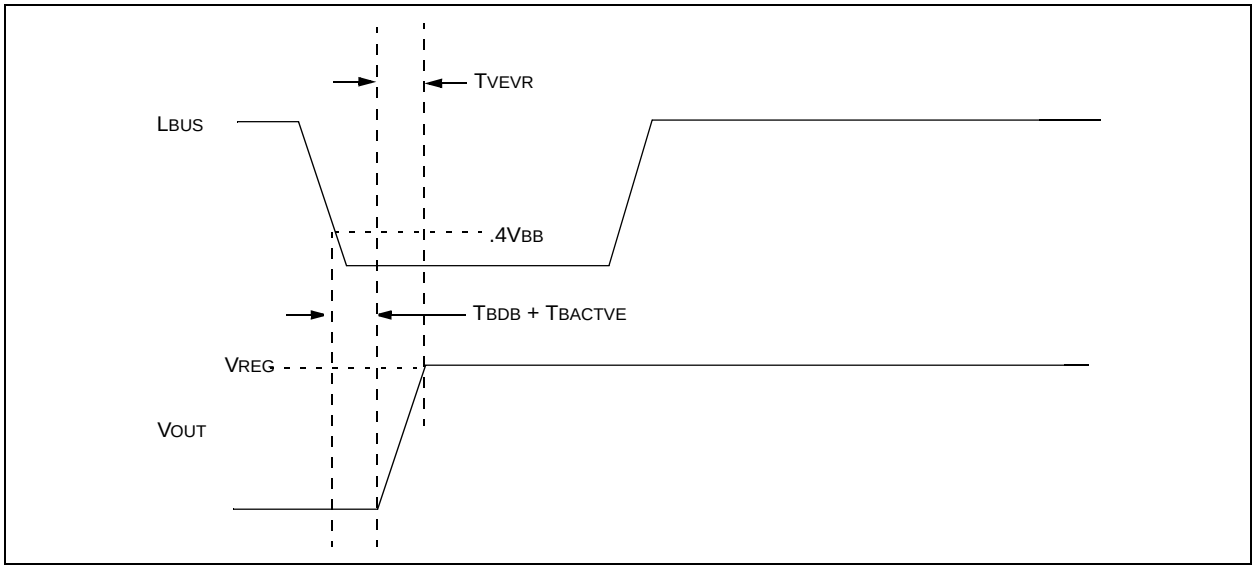


FIGURE 2-7: $\overline{\text{RESET}}$ TIMING DIAGRAM

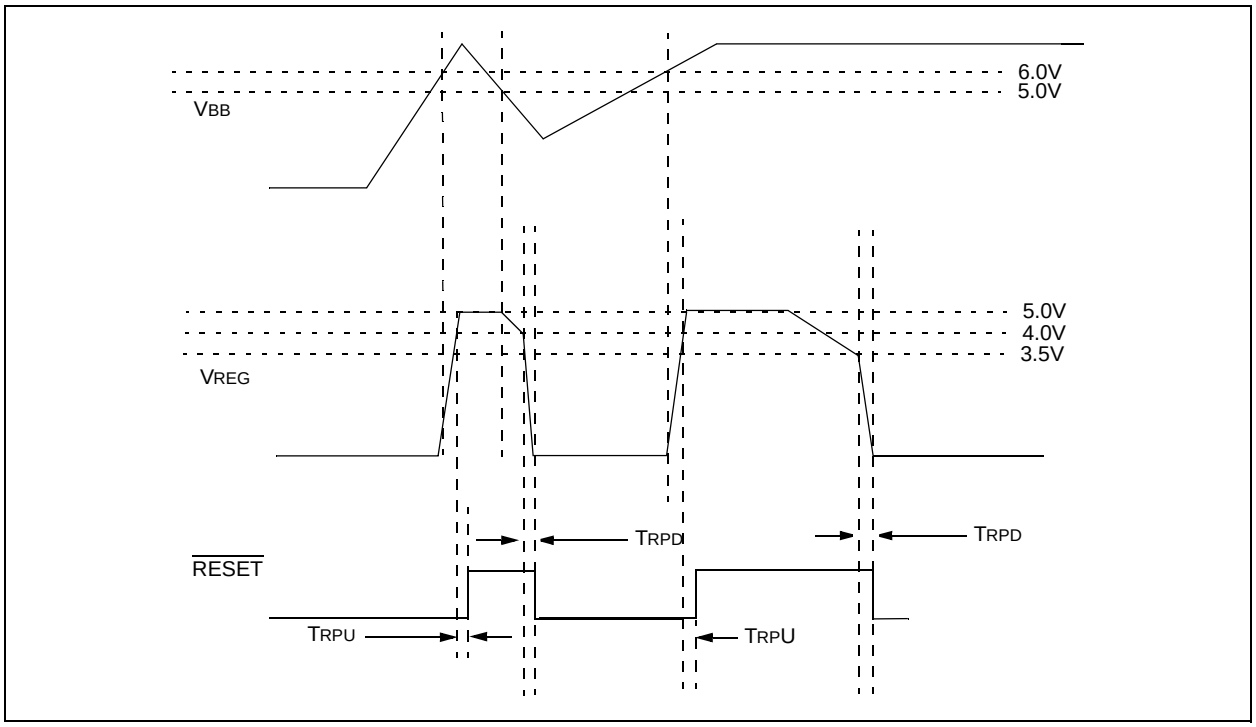


FIGURE 2-8: CS/LWAKE TO $\overline{\text{RESET}}$ TIMING DIAGRAM

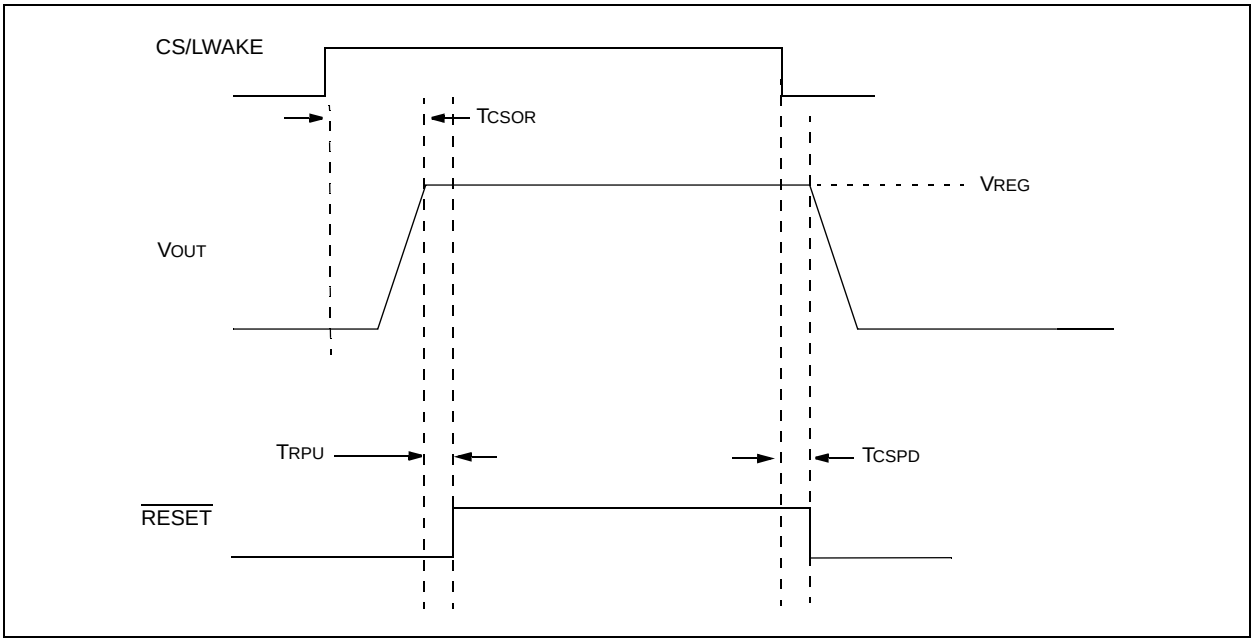


FIGURE 2-9: TYPICAL IBBQ VS. TEMPERATURE

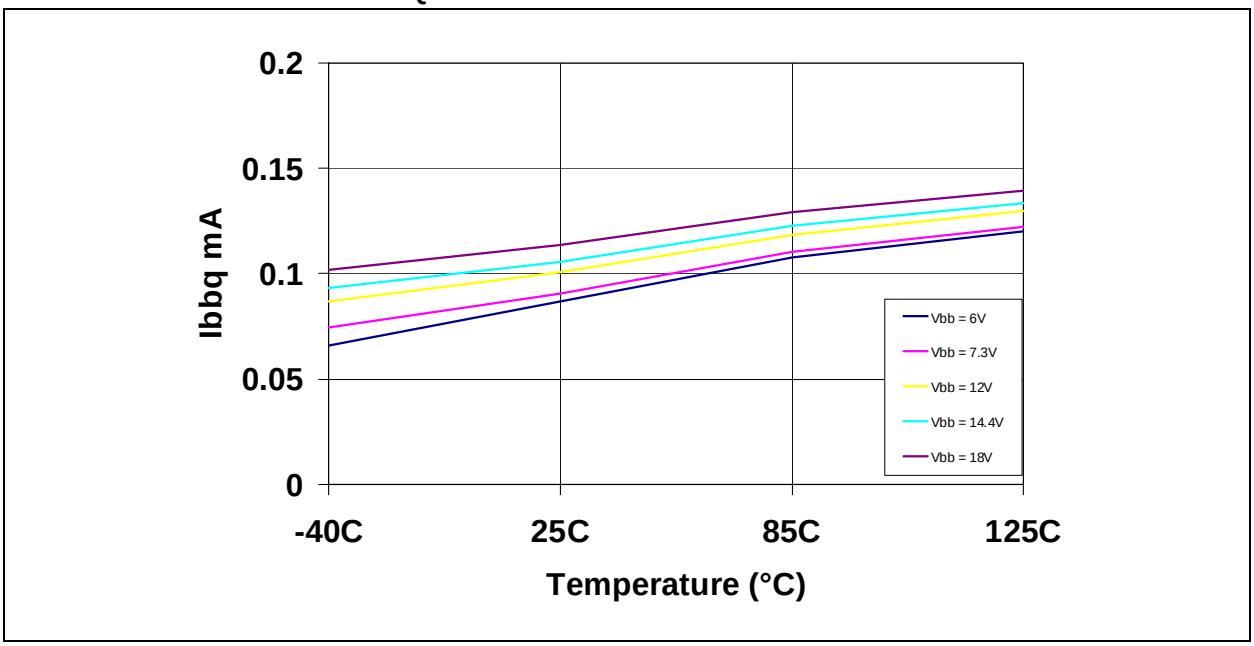


FIGURE 2-10: TYPICAL IBBTO VS TEMPERATURE

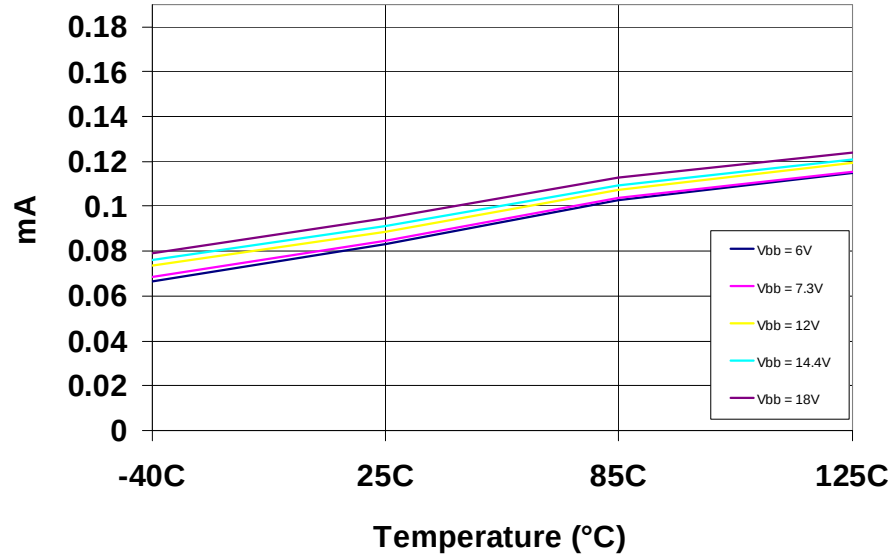
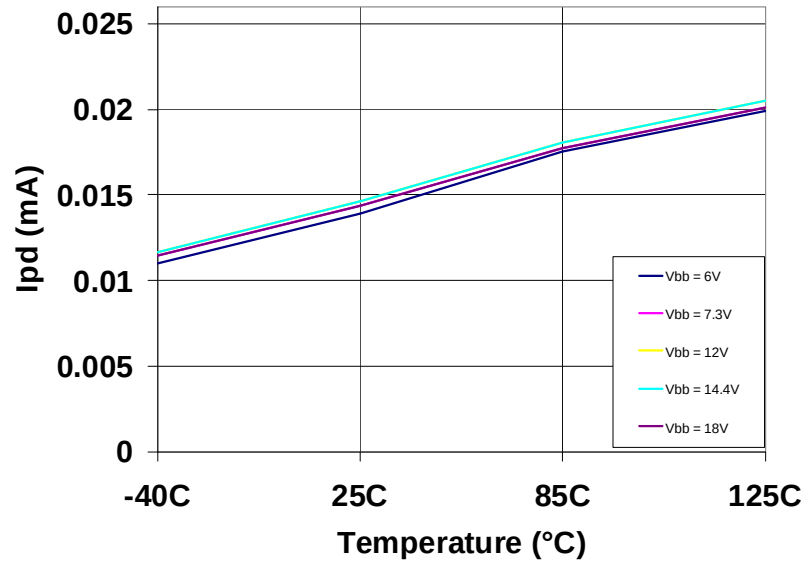


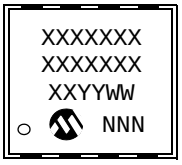
FIGURE 2-11: TYPICAL IPD VS. TEMPERATURE



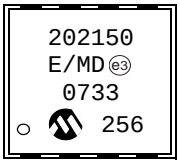
3.0 PACKAGING INFORMATION

3.1 Package Marking Information

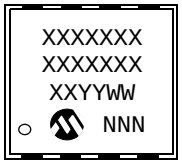
8-Lead DFN (4x4)



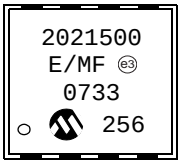
Example:



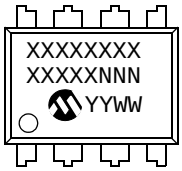
8-Lead DFN-S (6x5)



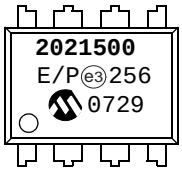
Example:



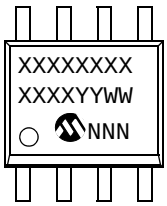
8-Lead PDIP (300 mil)



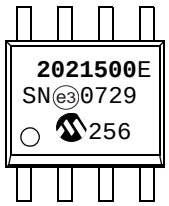
Example:



8-Lead SOIC (150 mil)



Example:

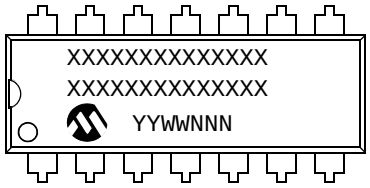


Legend:	XX...X	Customer-specific information
	Y	Year code (last digit of calendar year)
	YY	Year code (last 2 digits of calendar year)
	WW	Week code (week of January 1 is week ‘01’)
	NNN	Alphanumeric traceability code
	(e3)	Pb-free JEDEC designator for Matte Tin (Sn)
	*	This package is Pb-free. The Pb-free JEDEC designator ((e3)) can be found on the outer packaging for this package.

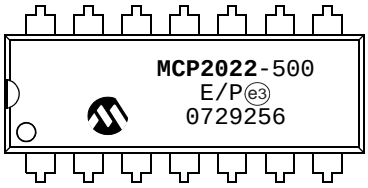
Note: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information.

3.1 Package Marking Information (Continued)

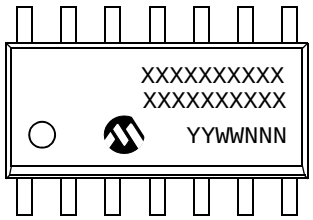
14-Lead PDIP (300 mil) **(MCP2022)**



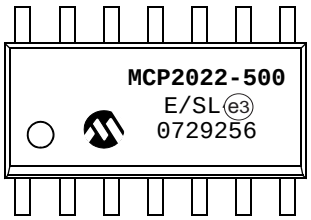
Example:



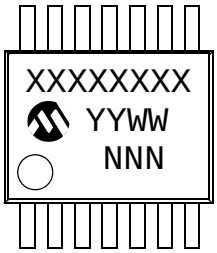
14-Lead SOIC (150 mil) **(MCP2022)**



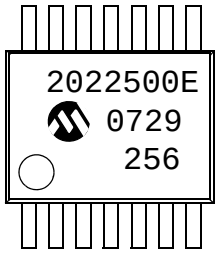
Example:



14-Lead TSSOP (**MCP2022**)



Example

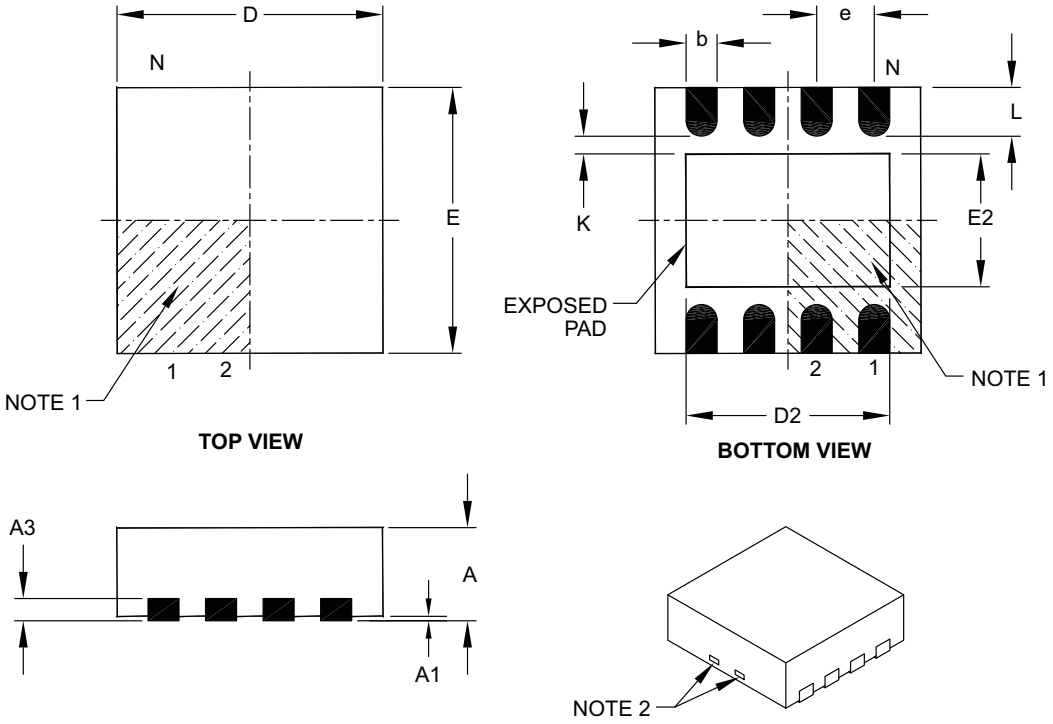


Legend:	XX...X	Customer-specific information
	Y	Year code (last digit of calendar year)
	YY	Year code (last 2 digits of calendar year)
	WW	Week code (week of January 1 is week ‘01’)
	NNN	Alphanumeric traceability code
	(e3)	Pb-free JEDEC designator for Matte Tin (Sn)
	*	This package is Pb-free. The Pb-free JEDEC designator ((e3)) can be found on the outer packaging for this package.

Note: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information.

8-Lead Plastic Dual Flat, No Lead Package (MD) – 4x4x0.9 mm Body [DFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Number of Pins	N		8	
Pitch	e		0.80 BSC	
Overall Height	A	0.80	0.90	1.00
Standoff	A1	0.00	0.02	0.05
Contact Thickness	A3		0.20 REF	
Overall Length	D		4.00 BSC	
Exposed Pad Width	E2	0.00	2.20	2.80
Overall Width	E		4.00 BSC	
Exposed Pad Length	D2	0.00	3.00	3.60
Contact Width	b	0.25	0.30	0.35
Contact Length	L	0.30	0.55	0.65
Contact-to-Exposed Pad	K	0.20	–	–

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.
2. Package may have one or more exposed tie bars at ends.
3. Package is saw singulated.
4. Dimensioning and tolerancing per ASME Y14.5M.

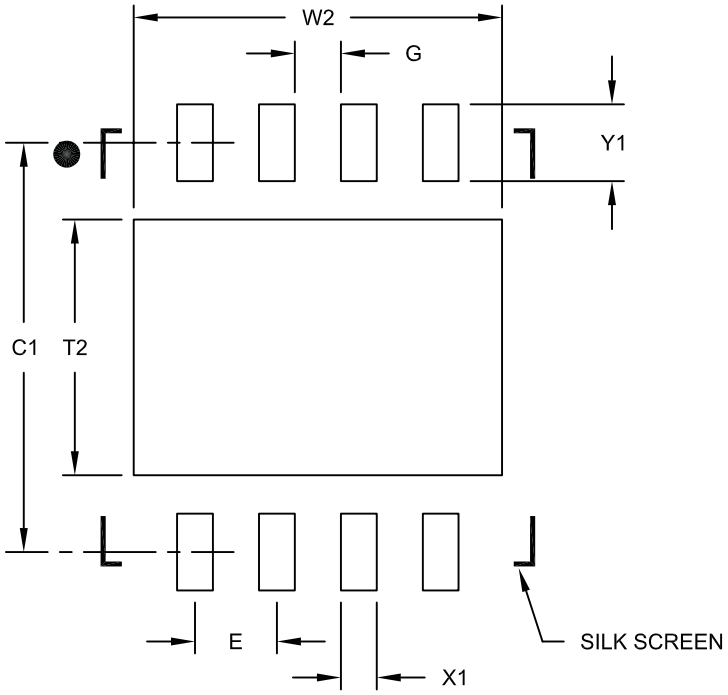
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-131C

8-Lead Plastic Dual Flat, No Lead Package (MD) – 4x4x0.9 mm Body [DFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Contact Pitch	E	0.80 BSC		
Optional Center Pad Width	W2			3.60
Optional Center Pad Length	T2			2.50
Contact Pad Spacing	C1		4.00	
Contact Pad Width (X8)	X1			0.35
Contact Pad Length (X8)	Y1			0.75
Distance Between Pads	G	0.45		

Notes:

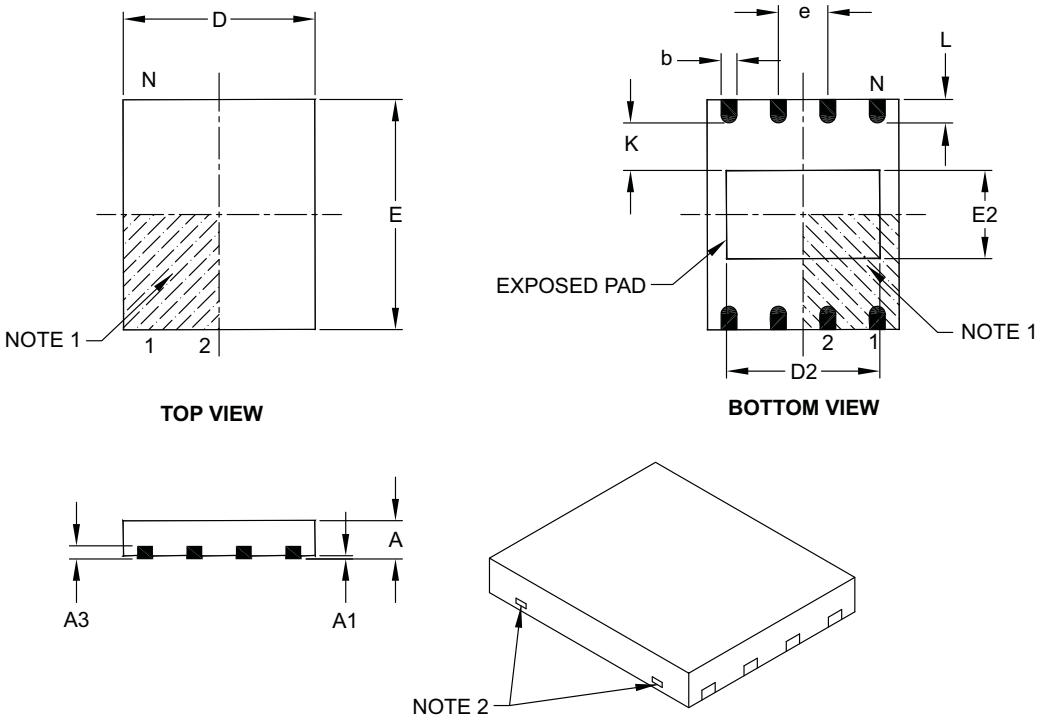
1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2131B

8-Lead Plastic Dual Flat, No Lead Package (MF) – 6x5 mm Body [DFN-S]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Number of Pins	N		8	
Pitch	e		1.27 BSC	
Overall Height	A	0.80	0.85	1.00
Standoff	A1	0.00	0.01	0.05
Contact Thickness	A3		0.20 REF	
Overall Length	D		5.00 BSC	
Overall Width	E		6.00 BSC	
Exposed Pad Length	D2	3.90	4.00	4.10
Exposed Pad Width	E2	2.20	2.30	2.40
Contact Width	b	0.35	0.40	0.48
Contact Length	L	0.50	0.60	0.75
Contact-to-Exposed Pad	K	0.20	–	–

Notes:

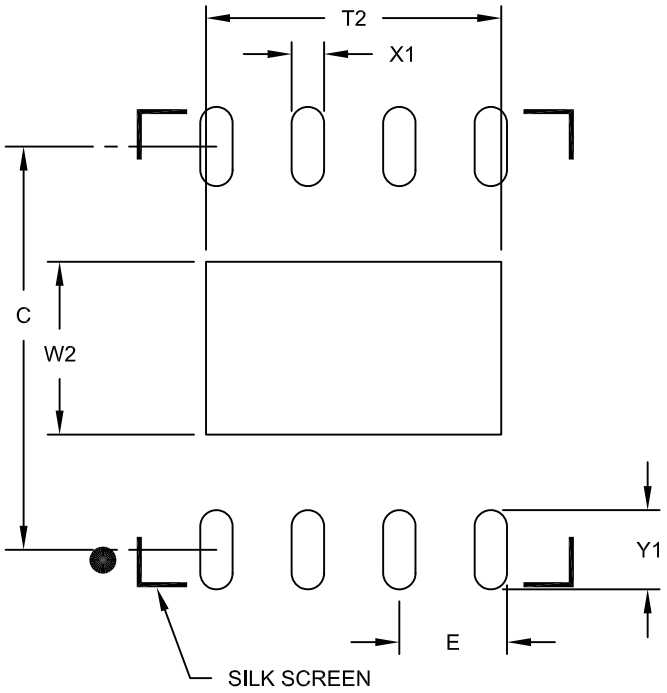
1. Pin 1 visual index feature may vary, but must be located within the hatched area.
2. Package may have one or more exposed tie bars at ends.
3. Package is saw singulated.
4. Dimensioning and tolerancing per ASME Y14.5M.

BSC: Basic Dimension. Theoretically exact value shown without tolerances.
REF: Reference Dimension, usually without tolerance, for information purposes only.

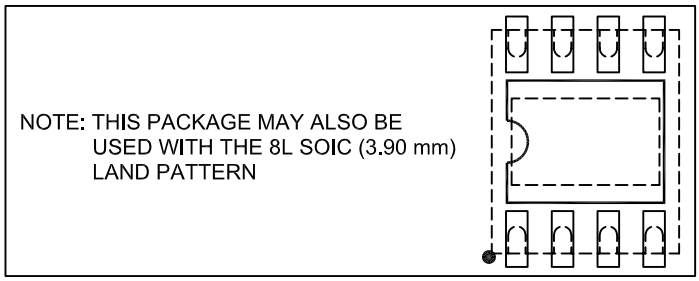
Microchip Technology Drawing C04-122B

8-Lead Plastic Dual Flat, No Lead Package (MF) - 6x5 mm Body [DFN-S]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN



Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Contact Pitch	E		1.27 BSC	
Optional Center Pad Width	W2			2.40
Optional Center Pad Length	T2			4.10
Contact Pad Spacing	C		5.60	
Contact Pad Width (X8)	X1			0.45
Contact Pad Length (X8)	Y1			1.10

Notes:

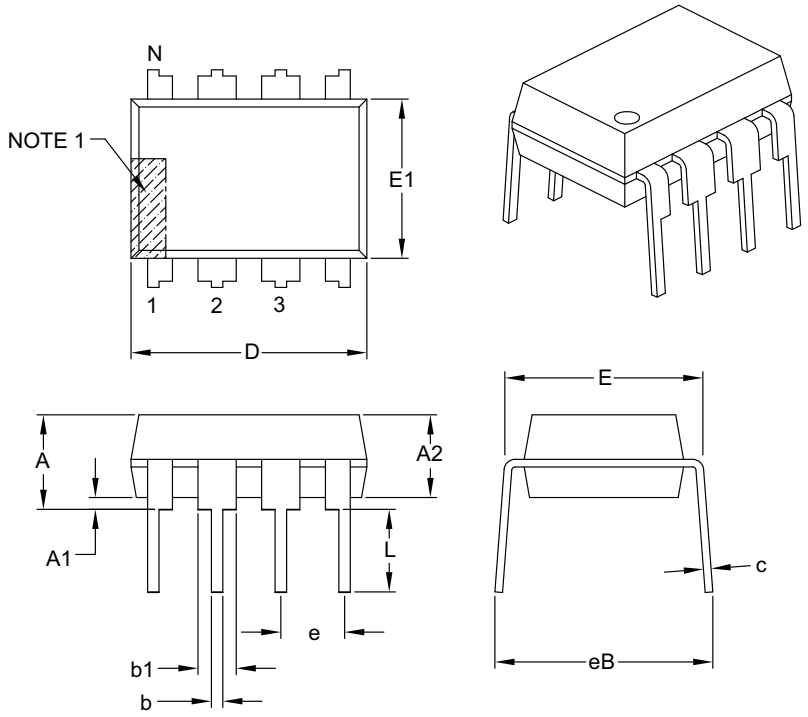
1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2122A

8-Lead Plastic Dual In-Line (P) – 300 mil Body [PDIP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Units		INCHES		
Dimension Limits		MIN	NOM	MAX
Number of Pins	N		8	
Pitch	e		.100 BSC	
Top to Seating Plane	A	–	–	.210
Molded Package Thickness	A2	.115	.130	.195
Base to Seating Plane	A1	.015	–	–
Shoulder to Shoulder Width	E	.290	.310	.325
Molded Package Width	E1	.240	.250	.280
Overall Length	D	.348	.365	.400
Tip to Seating Plane	L	.115	.130	.150
Lead Thickness	c	.008	.010	.015
Upper Lead Width	b1	.040	.060	.070
Lower Lead Width	b	.014	.018	.022
Overall Row Spacing §	eB	–	–	.430

Notes:

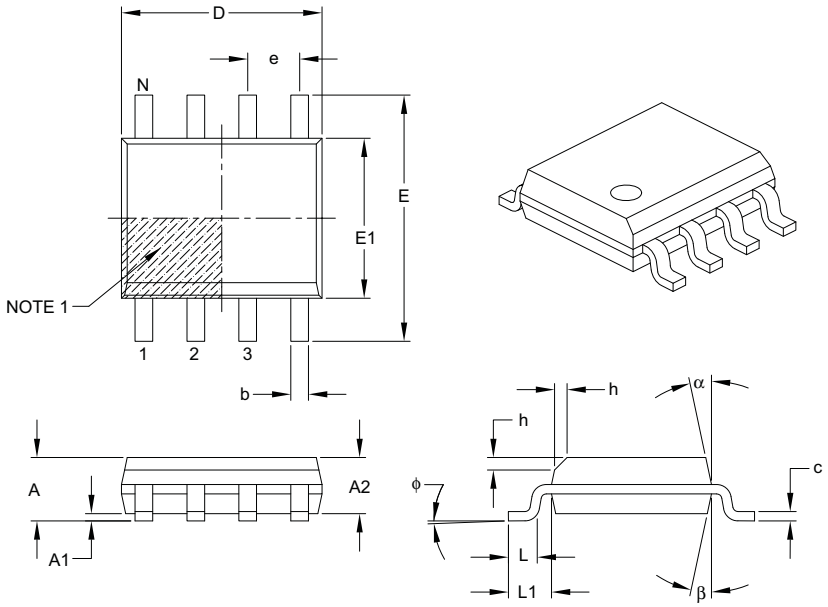
1. Pin 1 visual index feature may vary, but must be located with the hatched area.
2. § Significant Characteristic.
3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" per side.
4. Dimensioning and tolerancing per ASME Y14.5M.

   BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-018B

8-Lead Plastic Small Outline (SN) – Narrow, 3.90 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Number of Pins	N		8	
Pitch	e		1.27 BSC	
Overall Height	A	–	–	1.75
Molded Package Thickness	A2	1.25	–	–
Standoff §	A1	0.10	–	0.25
Overall Width	E		6.00 BSC	
Molded Package Width	E1		3.90 BSC	
Overall Length	D		4.90 BSC	
Chamfer (optional)	h	0.25	–	0.50
Foot Length	L	0.40	–	1.27
Footprint	L1		1.04 REF	
Foot Angle	φ	0°	–	8°
Lead Thickness	c	0.17	–	0.25
Lead Width	b	0.31	–	0.51
Mold Draft Angle Top	α	5°	–	15°
Mold Draft Angle Bottom	β	5°	–	15°

Notes:

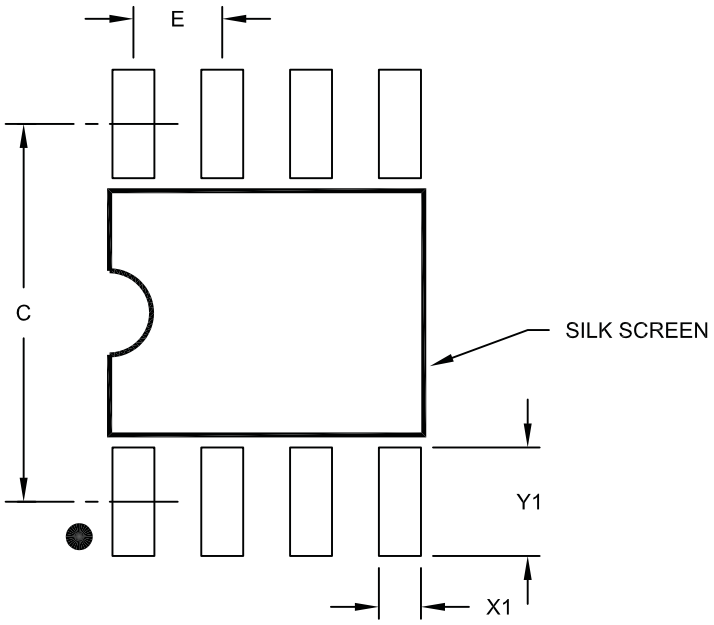
1. Pin 1 visual index feature may vary, but must be located within the hatched area.
2. § Significant Characteristic.
3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15 mm per side.
4. Dimensioning and tolerancing per ASME Y14.5M.

BSC: Basic Dimension. Theoretically exact value shown without tolerances.
REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-057B

8-Lead Plastic Small Outline (SN) – Narrow, 3.90 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Contact Pitch	E		1.27 BSC	
Contact Pad Spacing	C		5.40	
Contact Pad Width (X8)	X1			0.60
Contact Pad Length (X8)	Y1			1.55

Notes:

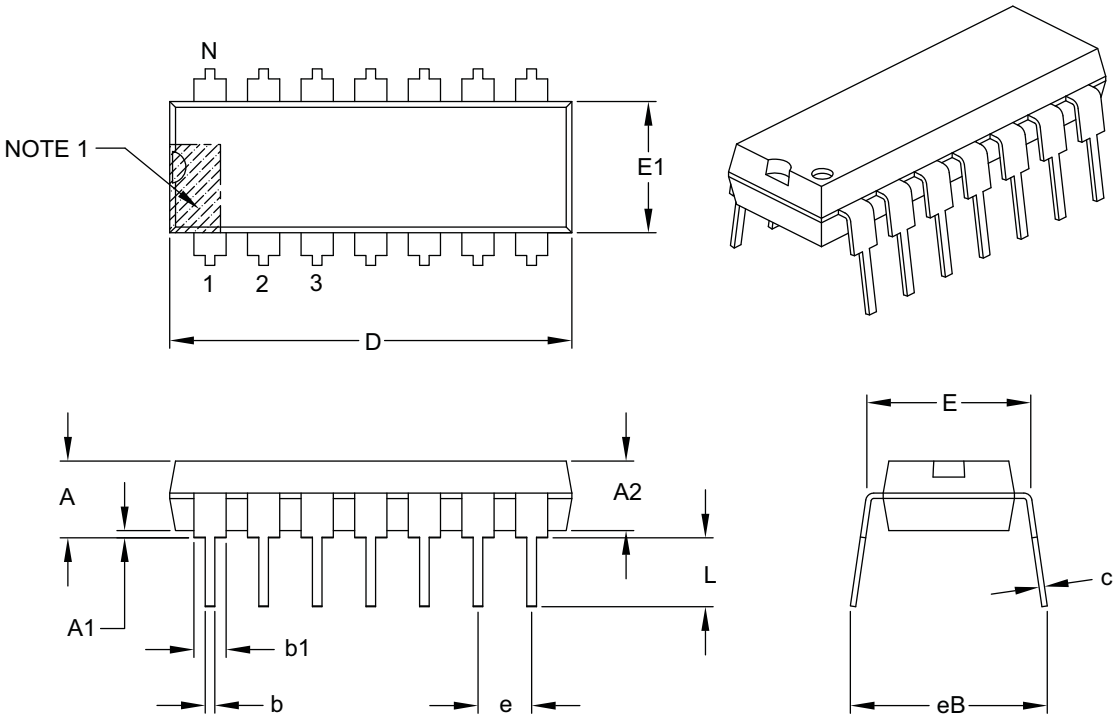
1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2057A

14-Lead Plastic Dual In-Line (P) – 300 mil Body [PDIP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Units		INCHES		
Dimension Limits		MIN	NOM	MAX
Number of Pins	N		14	
Pitch	e		.100 BSC	
Top to Seating Plane	A	–	–	.210
Molded Package Thickness	A2	.115	.130	.195
Base to Seating Plane	A1	.015	–	–
Shoulder to Shoulder Width	E	.290	.310	.325
Molded Package Width	E1	.240	.250	.280
Overall Length	D	.735	.750	.775
Tip to Seating Plane	L	.115	.130	.150
Lead Thickness	c	.008	.010	.015
Upper Lead Width	b1	.045	.060	.070
Lower Lead Width	b	.014	.018	.022
Overall Row Spacing §	eB	–	–	.430

Notes:

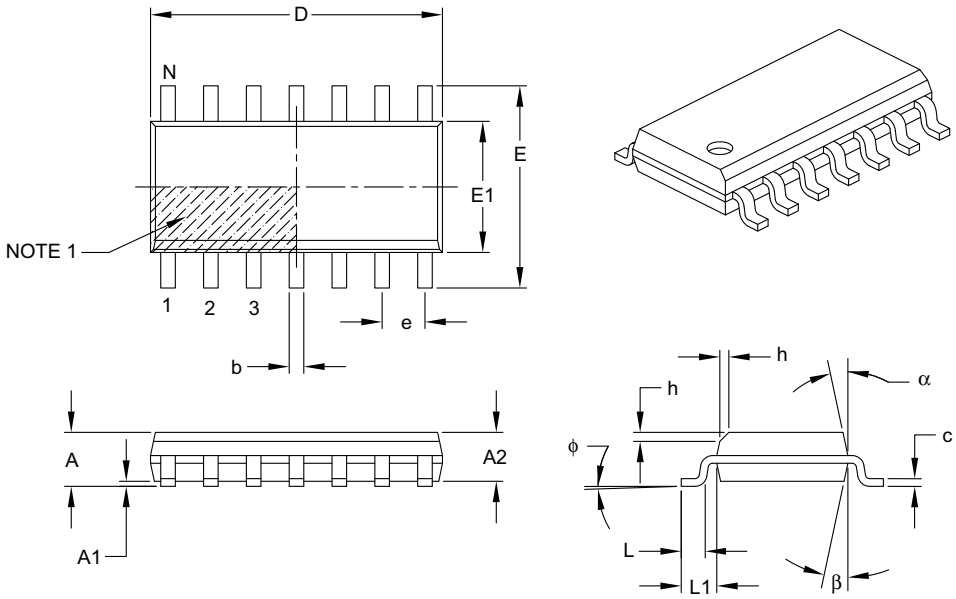
1. Pin 1 visual index feature may vary, but must be located with the hatched area.
2. § Significant Characteristic.
3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" per side.
4. Dimensioning and tolerancing per ASME Y14.5M.

   BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-005B

14-Lead Plastic Small Outline (SL) – Narrow, 3.90 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Number of Pins	N		14	
Pitch	e		1.27 BSC	
Overall Height	A	–	–	1.75
Molded Package Thickness	A2	1.25	–	–
Standoff §	A1	0.10	–	0.25
Overall Width	E		6.00 BSC	
Molded Package Width	E1		3.90 BSC	
Overall Length	D		8.65 BSC	
Chamfer (optional)	h	0.25	–	0.50
Foot Length	L	0.40	–	1.27
Footprint	L1		1.04 REF	
Foot Angle	φ	0°	–	8°
Lead Thickness	c	0.17	–	0.25
Lead Width	b	0.31	–	0.51
Mold Draft Angle Top	α	5°	–	15°
Mold Draft Angle Bottom	β	5°	–	15°

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.
2. § Significant Characteristic.
3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15 mm per side.
4. Dimensioning and tolerancing per ASME Y14.5M.

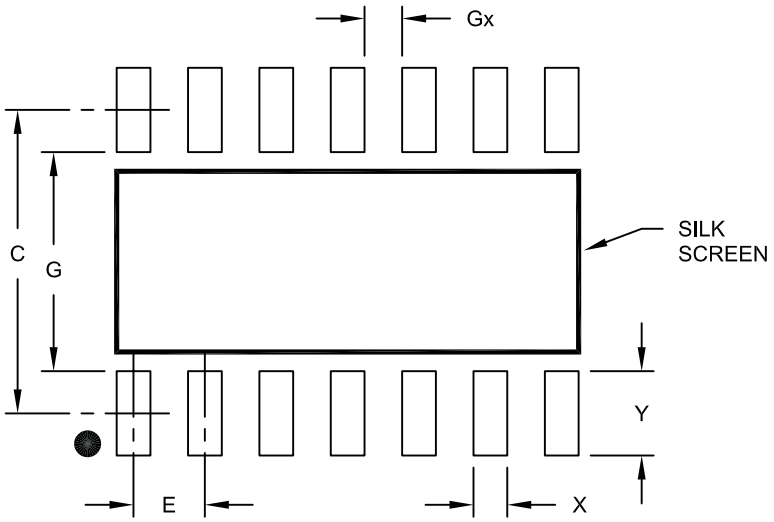
   BSC: Basic Dimension. Theoretically exact value shown without tolerances.

   REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-065B

14-Lead Plastic Small Outline (SL) - Narrow, 3.90 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Contact Pitch	E		1.27 BSC	
Contact Pad Spacing	C		5.40	
Contact Pad Width	X			0.60
Contact Pad Length	Y			1.50
Distance Between Pads	Gx	0.67		
Distance Between Pads	G	3.90		

Notes:

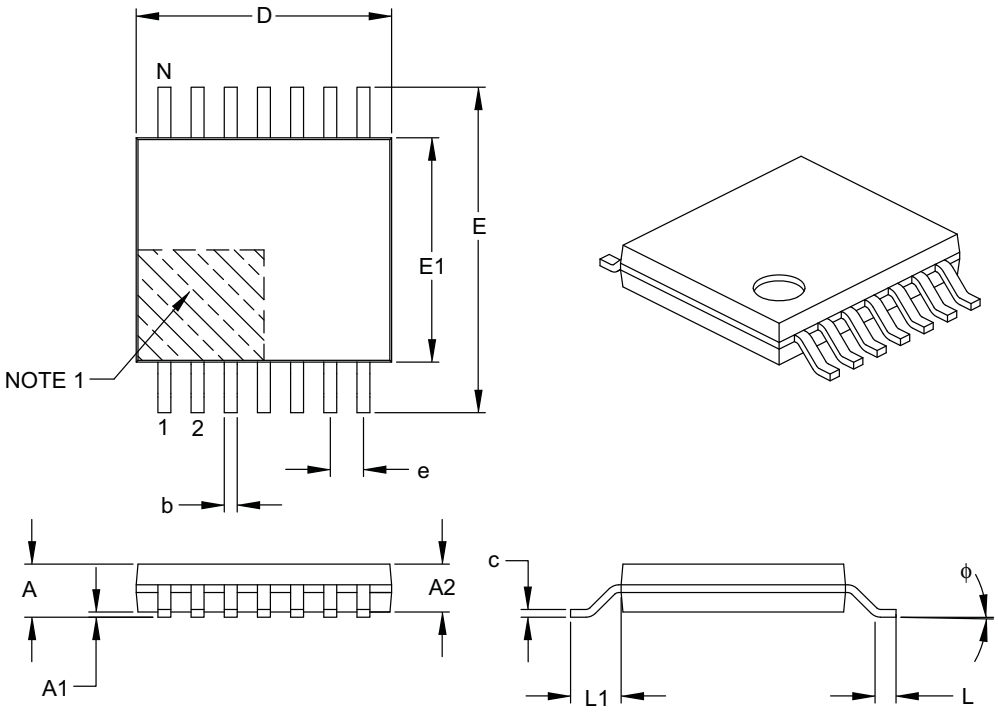
1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2065A

14-Lead Plastic Thin Shrink Small Outline (ST) – 4.4 mm Body [TSSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Number of Pins	N		14	
Pitch	e		0.65 BSC	
Overall Height	A	–	–	1.20
Molded Package Thickness	A2	0.80	1.00	1.05
Standoff	A1	0.05	–	0.15
Overall Width	E		6.40 BSC	
Molded Package Width	E1	4.30	4.40	4.50
Molded Package Length	D	4.90	5.00	5.10
Foot Length	L	0.45	0.60	0.75
Footprint	L1		1.00 REF	
Foot Angle	ϕ	0°	–	8°
Lead Thickness	c	0.09	–	0.20
Lead Width	b	0.19	–	0.30

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.
2. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15 mm per side.
3. Dimensioning and tolerancing per ASME Y14.5M.

BSC: Basic Dimension. Theoretically exact value shown without tolerances.
REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-087B

NOTES:

APPENDIX A: REVISION HISTORY

Revision E (February 2009)

The following is the list of modifications.

1. Added Example 1-2 and Example 1-3.
2. Updated **Section 1.5.9 "RESET"**.
3. Updated **Section 1.7 "ICSP™ Considerations"**.
4. Updated **Section 2.1 "Absolute Maximum Ratings†"**.
5. Updated **Section 2.2 "DC Specifications"** and **Section 2.3 "AC Specification"**.
6. Added **FIGURE 2-3: "ESR Curves For Load Capacitor Selection"**.
7. Updated the Product Identification System section.

Revision D (July 2008)

The following is the list of modifications.

1. Updated ESD specs under 'Absolute DC'.
2. Updated notes in Example 1-1.
3. Updated Package Outline Drawings.

Revision C (April 2008)

The following is the list of modifications.

1. Added LIN2.1 and J2602 compliance statement to Features section.
2. Added recommended RC network for CS/LWAKE in Example 1-1.
3. Updated 2.1 Absolute Maximum Ratings to reflect current test results.
4. Updated 2.2 DC Specifications and 2.3 AC Specifications to reflect current production device.
5. Added 8-Lead SOIC Landing Pattern Outline drawing.

Revision B (August 2007)

The following is the list of modifications:

1. Modified Block Diagram on page 2.
2. **Section 1.3.5 "Transmitter OFF Mode"**: Deleted text in 1st paragraph.
3. **Example 1-1**: Removed +5V notation.
4. **Section 1.5 "Pin Descriptions"**: Removed 10-pin DFN, MSOP column from table.
5. **Section 1.5.8 "Fault/TXE"**: Deleted text from 2nd paragraph.
6. **Section 3.0 "Packaging Information"**: Added 8-lead 4x4 and 6x5 DFN and 14-lead TSSOP packages. Updated package outline drawings and added drawings for 8-lead DFN and 14-lead TSSOP drawings.

Revision A (November 2005)

- Original Release of this Document.

NOTES:

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

PART NO.	–X	/XX
Device	Temperature Range	Package

Device:	MCP2021:	LIN Transceiver with Voltage Regulator
	MCP2021T:	LIN Transceiver with Voltage Regulator (Tape and Reel) (SOIC only)
	MCP2022:	LIN Transceiver with Voltage Regulator
	MCP2022T:	LIN Transceiver with Voltage Regulator (Tape and Reel) (SOIC only)
Temperature Range:	E =	-40°C to +125°C
Package:	MD =	Plastic Micro Small Outline (4x4), 8-lead
	MF =	Plastic Micro Small Outline (6x5), 8-lead
	P =	Plastic DIP (300 mil Body), 8-lead, 14-lead
	SN =	Plastic SOIC, (150 mil Body), 8-lead
	SL =	Plastic SOIC, (150 mil Body), 14-lead
	ST =	Plastic Thin Shrink Small Outline, 14-lead

Examples:

a)	MCP2021-330E/SN:	3.3V, 8L-SOIC pkg.
b)	MCP2021-330E/P:	3.3V, 8L-PDIP pkg.
c)	MCP2021-500E/MF:	5.0V, 8L-DFN-S pkg.
d)	MCP2021-500E/SN:	5.0V, 8L-SOIC pkg.
e)	MCP2021-500E/MD:	5.0V, 8L-DFN pkg.
f)	MCP2021-330E/P:	5.0V, 8L-PDIP pkg.
g)	MCP2021T-330E/SN:	Tape and Reel, 3.3V, 8L-SOIC pkg.
h)	MCP2021T-500E/MD:	Tape and Reel, 5.0V, 8L-DFN pkg.
i)	MCP2021T-500E/SN:	Tape and Reel, 5.0V, 8L-SOIC pkg.
a)	MCP2022-330E/SL:	3.3V, 14L-SOIC pkg.
b)	MCP2022-330E/P:	3.3V, 14L-PDIP pkg.
c)	MCP2022-500E/SL:	5.0V, 14L-SOIC pkg.
d)	MCP2022-500E/P:	5.0V, 14L-PDIP pkg.
e)	MCP2022T-330E/SL:	Tape and Reel, 3.3V, 14L-SOIC pkg.
f)	MCP2022T-500E/SL:	Tape and Reel, 5.0V, 14L-SOIC pkg.
g)	MCP2022T-500E/ST:	Tape and Reel, 5.0V, 14L-TSSOP pkg.

NOTES:

Note the following details of the code protection feature on Microchip devices:

- Microchip products meet the specification contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is one of the most secure families of its kind on the market today, when used in the intended manner and under normal conditions.
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